

Examples of Specific Laser Systems

➤ Gas Lasers

CO₂ (9-10 μm), High Power
He:Ne (632 nm) , Ar (ion) Laser (520 nm)
Excimer (UV) Lithography

➤ Solid-State Lasers

Nd:YAG , Ti:Sapphire (Ultrafast Revolution)

➤ Fiber Lasers (Rare-Earth Doped Fiber Lasers)

Yb³⁺ (5+ kW), Tm³⁺ , Ho³⁺ (2 μm), Er³⁺ (1.5 μm)

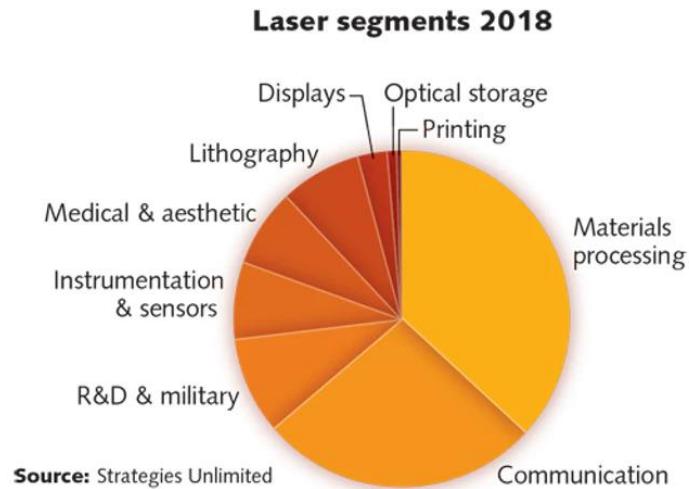
➤ Dye Lasers

➤ Chemical Lasers

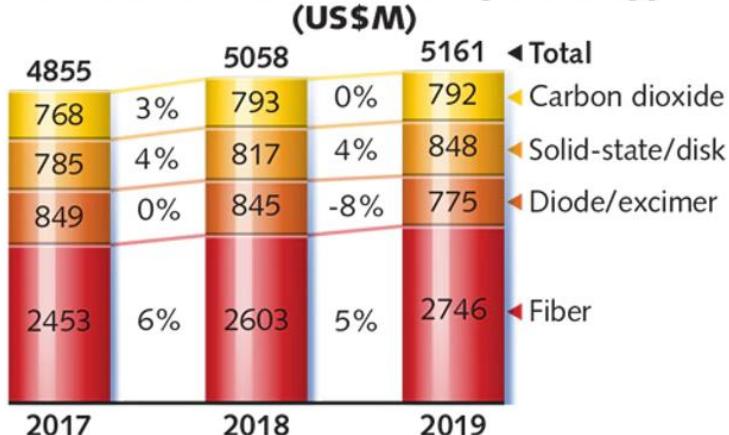
COIL (7+kW), MIRACL (>1 MW !!)

➤ Semiconductor Lasers

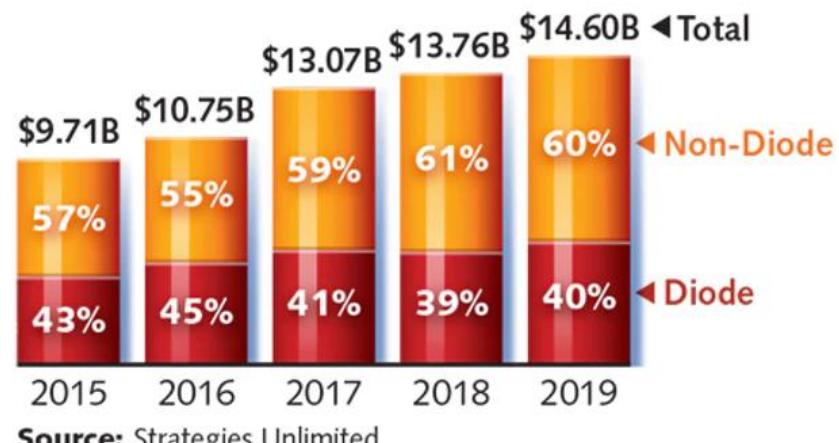
Laser Market and Applications

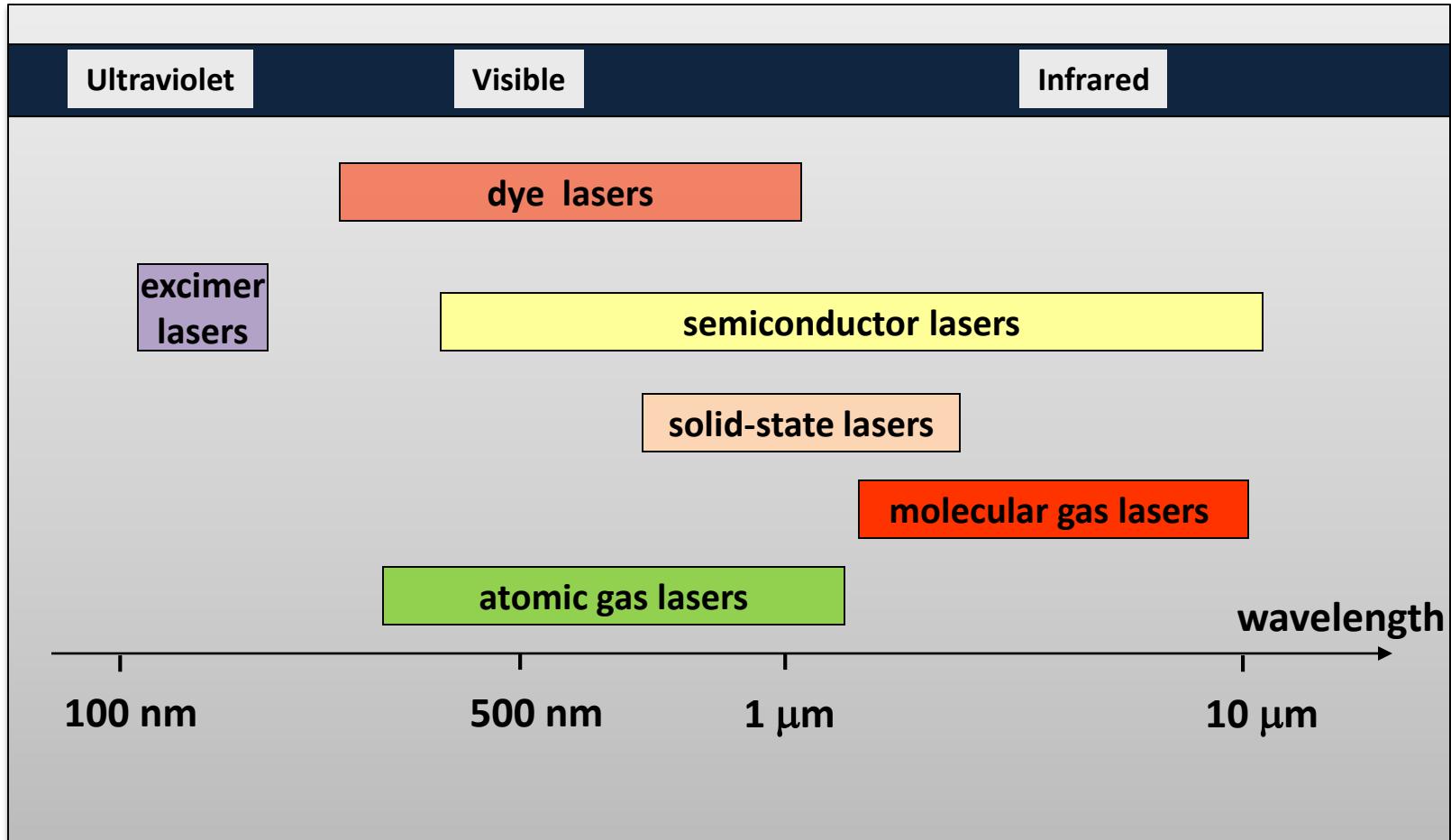


Industrial Laser Revenues by Laser Type

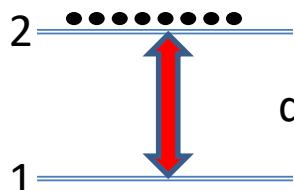


Laser revenues and 2019 forecast





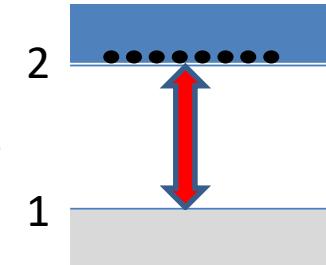
Optical Transitions



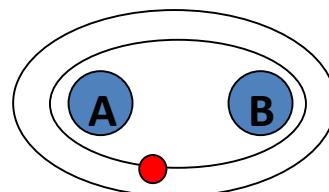
discrete levels

OR

energy bands



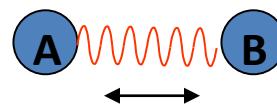
electronic transitions



emission

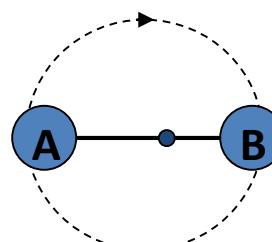
VIS, UV

vibrational transitions

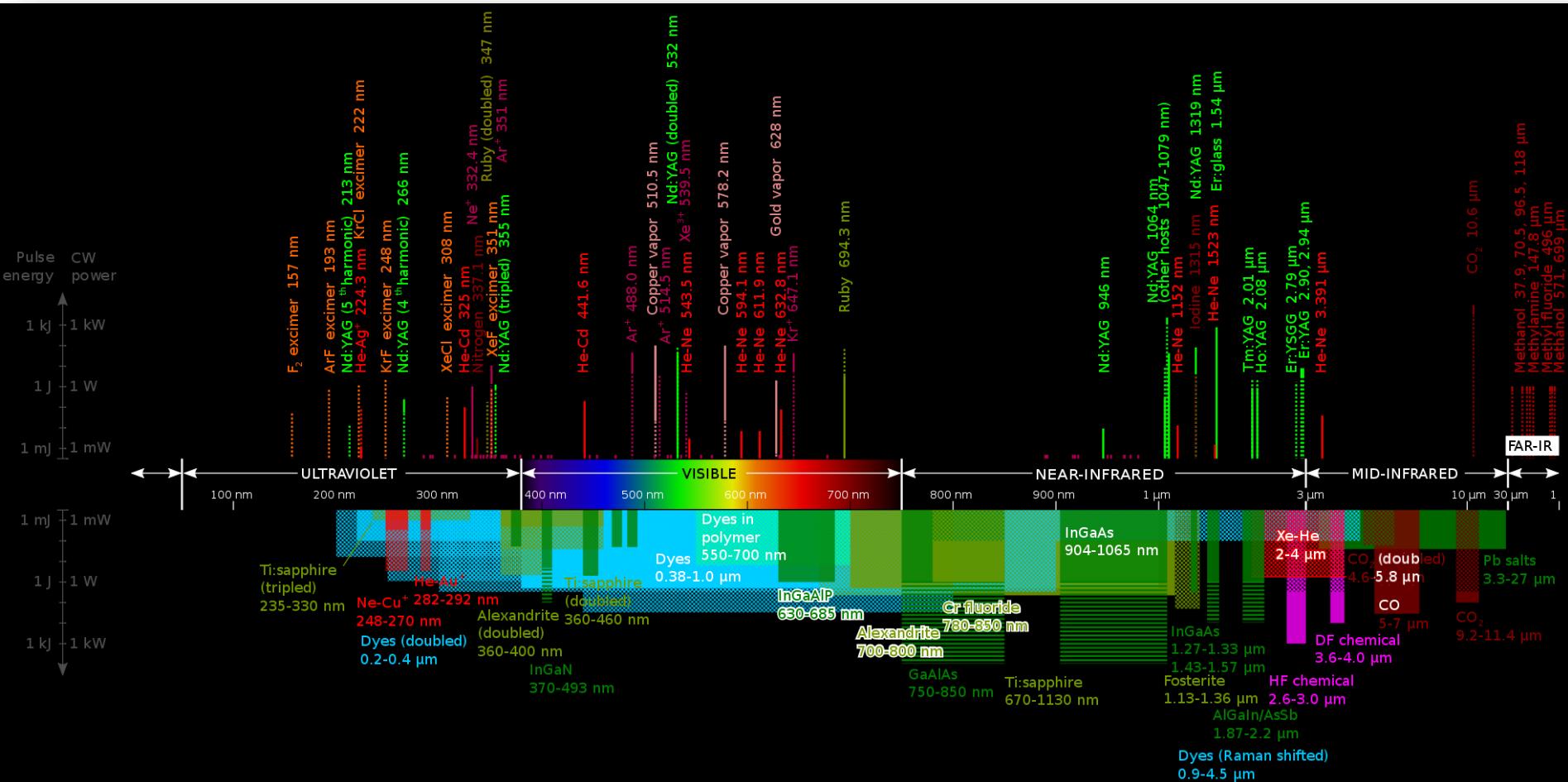


NIR, IR

rotational transitions



FIR

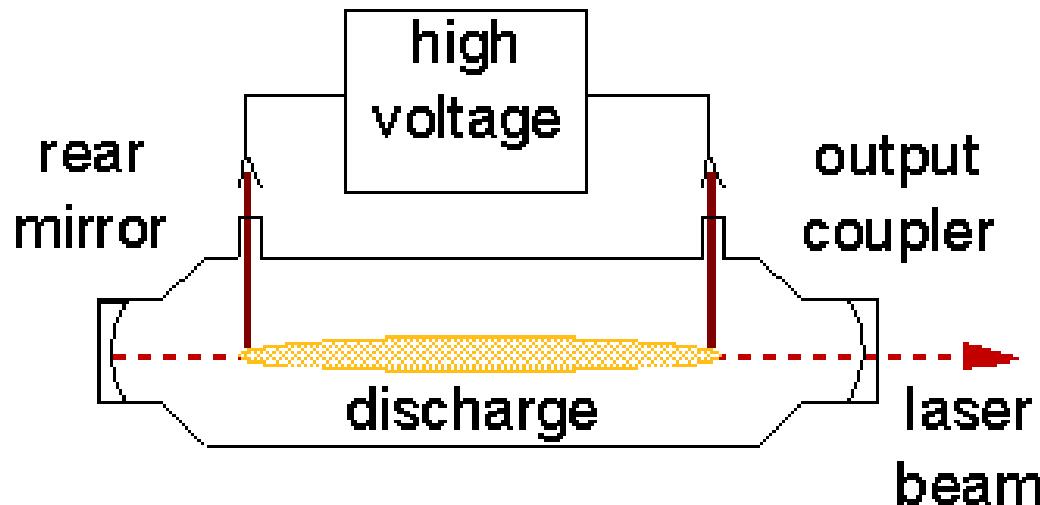


Typical laser efficiencies η :

$$\eta = \frac{\text{output power}}{\text{electrical input power}}$$

Argon - ion	< 0.1%
CO ₂ laser	< 20%
Excimer	< 20%
GaAlAs (diode laser)	< 40%
HeNe	< 0.1%
Nd:YAG	< 10%

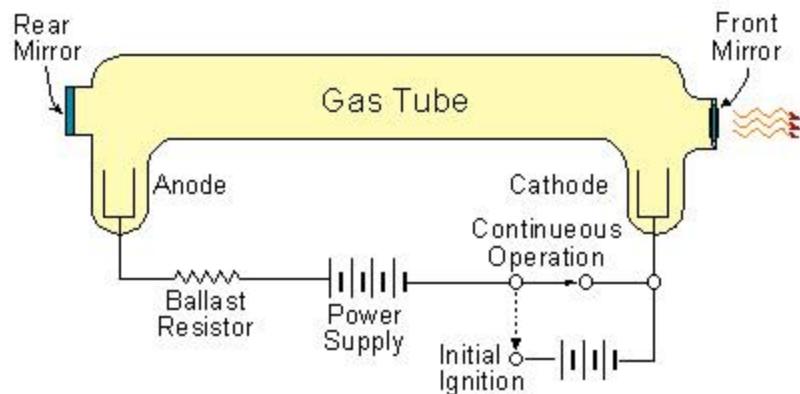
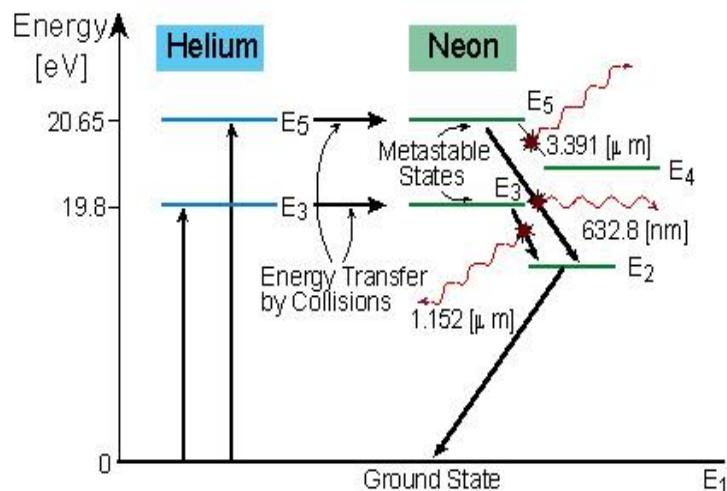
Gas Lasers (Examples: HeNe, Ar⁺, Excimer, CO₂,...)



The excitation mechanism in most gas lasers is via *electric discharge*

The first Gas Laser: He-Ne

Ali Javan, et al. (Bell Labs, 1962)



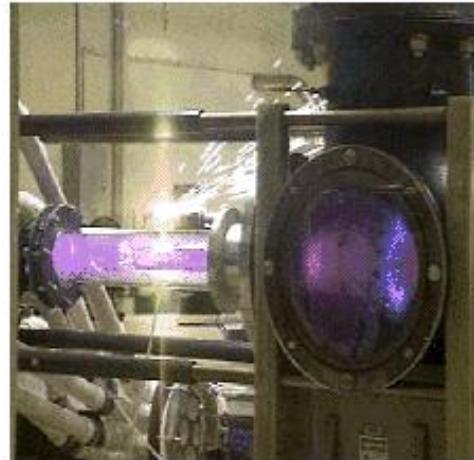
- The second working LASER system to be demonstrated.
- The first gas LASER to be produced.
- The first LASER to produce a continuous output beam
- The active laser medium is a gaseous mixture of He & Ne atoms, in a roughly 10:1 proportion
- The gas is enclosed in a cylindrical quartz DISCHARGE tube

Comparison of Gas Lasers

<i>Laser Type</i>	<i>Linear Power Density W/m</i>	<i>Maximum Power W</i>	<i>Power Efficiency %</i>
He-Ne	0.1	1	0.1
Argon	1-10	50	0.1
CO ₂	60-80	>10 ⁴	15-20

CO₂ Lasers (9-11 micron)

C. K. N. Patel, "Continuous-Wave Laser Action on Vibrational Rotational Transitions of CO₂," Physics Review, Vol. 136 A, (Nov., 1964) P. 1187

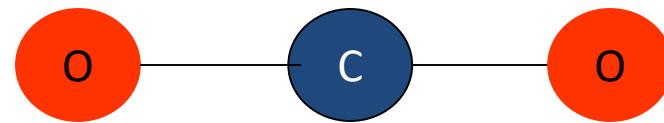


Applications (*peeling peanuts to star wars*)

- Industrial (cutting, welding, material processing)
- Military (range finding, targeting, remote sensing, sensor blinding, destroying ...)
- Medical (cutting, skin resurfacing)
-

Molecular Vibrations and Rotations

- Transitions are between molecular vibrational-rotational levels.

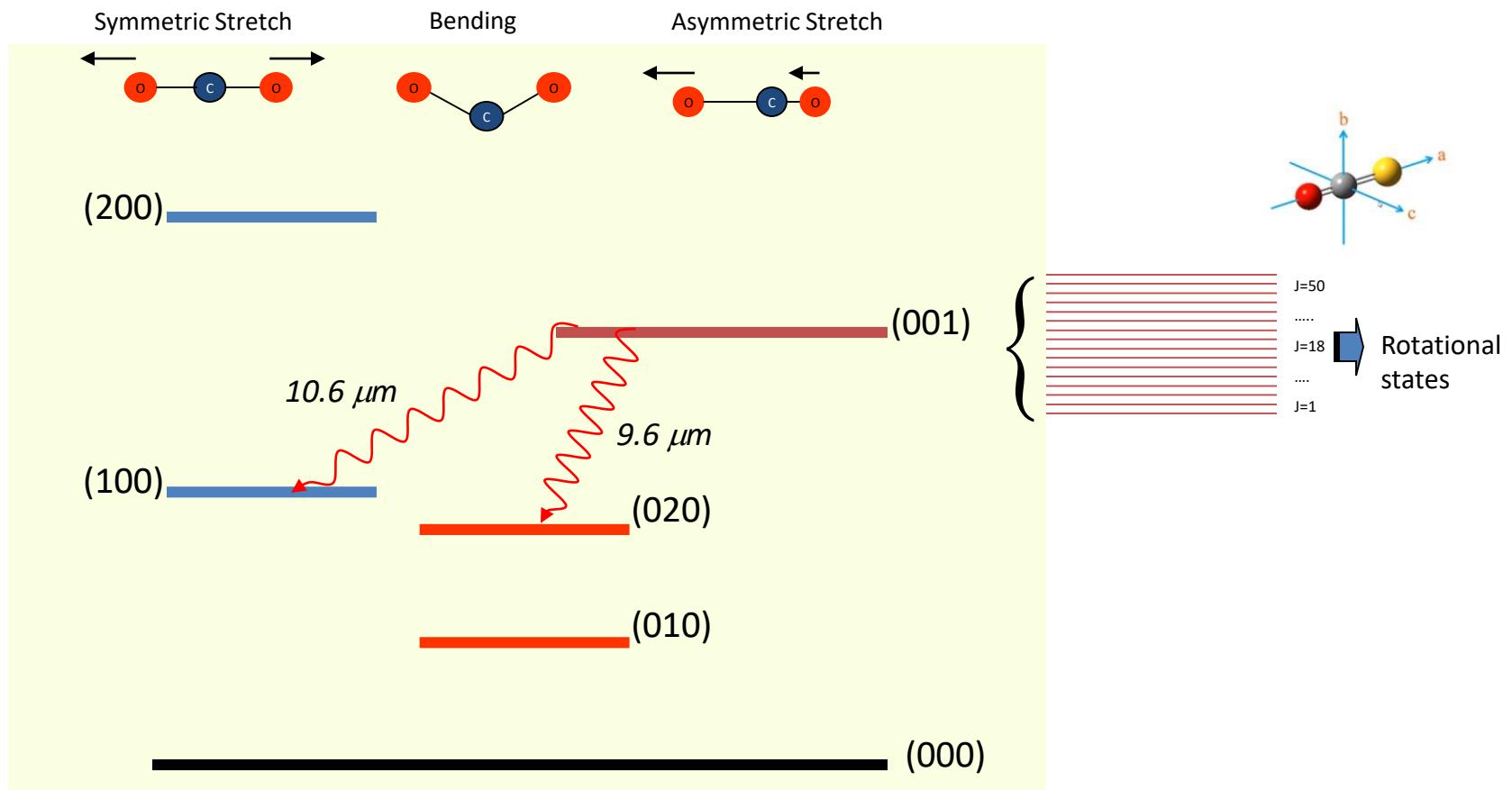


Modes of vibrations:

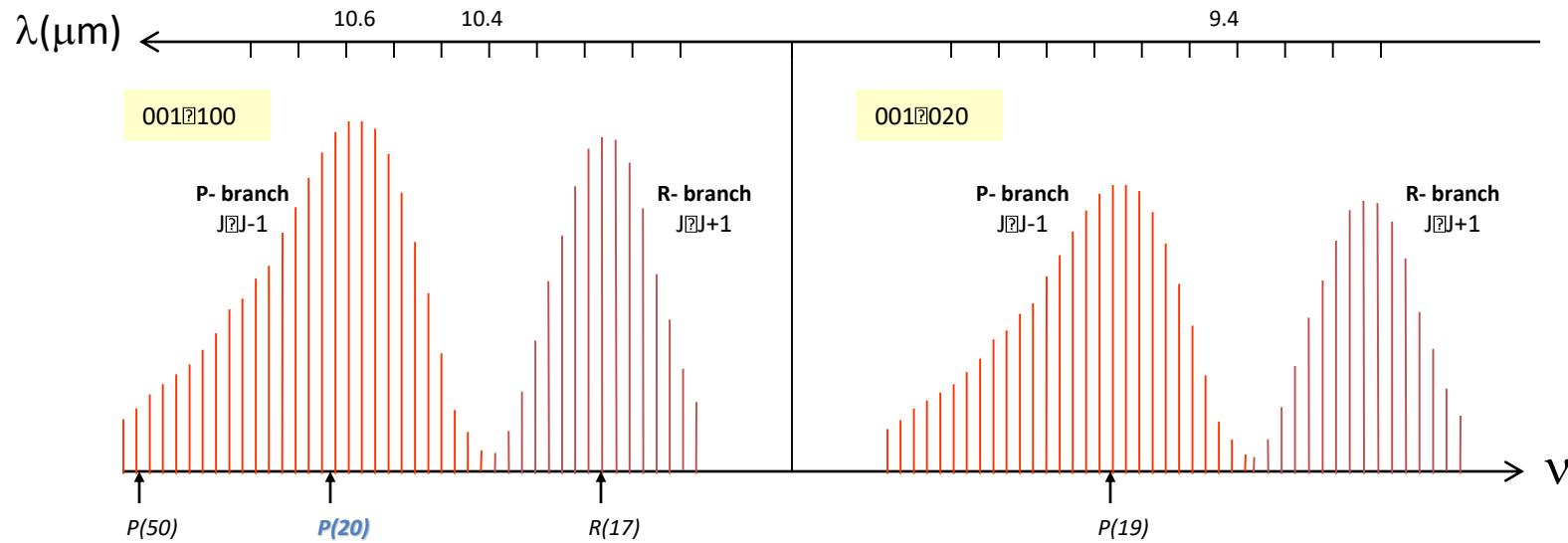
- Symmetric stretch
- Asymmetric stretch
- Bending mode

Simple Harmonic Oscillator (Quantum Mechanics):

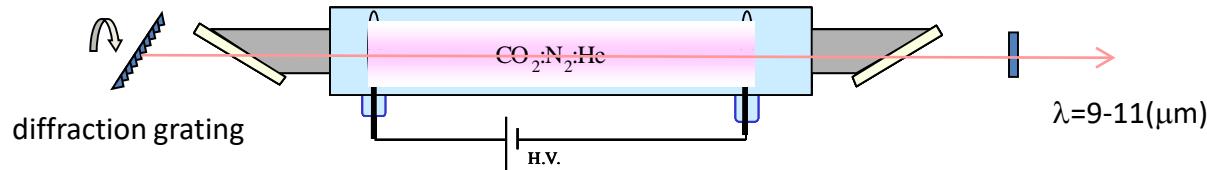
$$E(n_1, n_2, n_3) = h\nu_1(n_1 + 1/2) + h\nu_2(n_2 + 1/2) + h\nu_3(n_3 + 1/2)$$



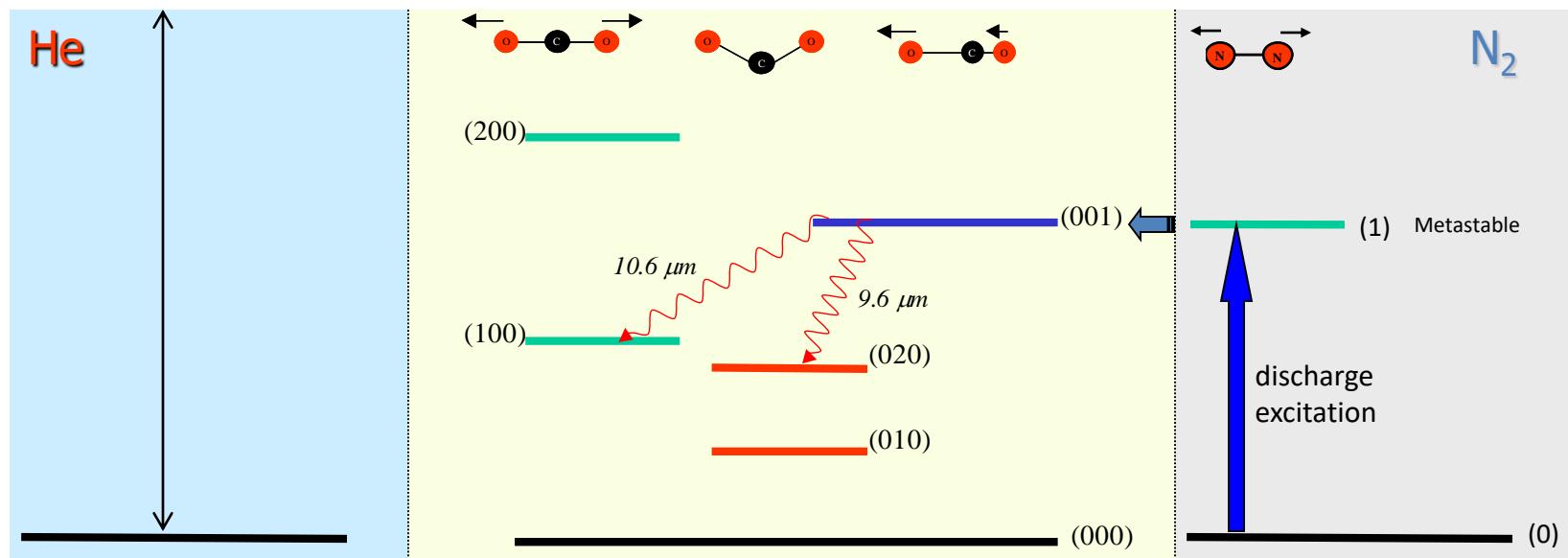
CO₂ Laser Transitions



Tuning:



Effect of Gas Mixtures: $\text{CO}_2 + \text{N}_2 + \text{He}$



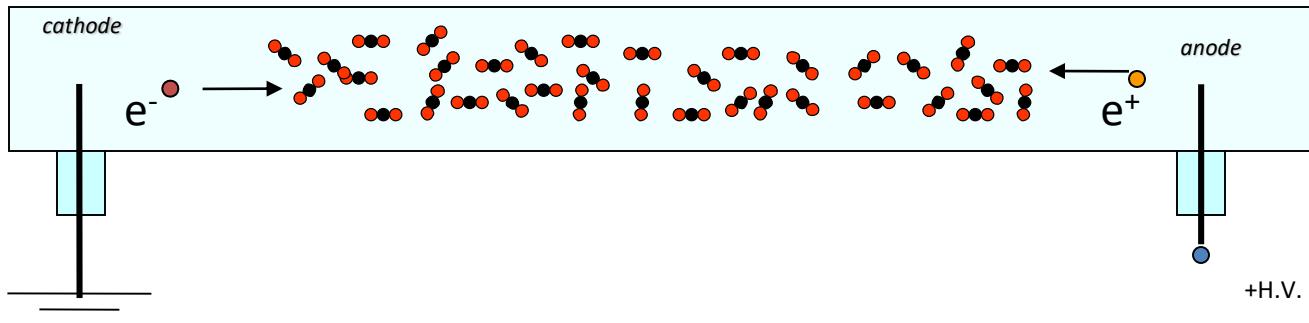
- Nitrogen helps populating the upper laser level in a discharge
- Helium helps to depopulate the lower laser level by collisions

Other possible additions to the gas mixture: CO , H_2

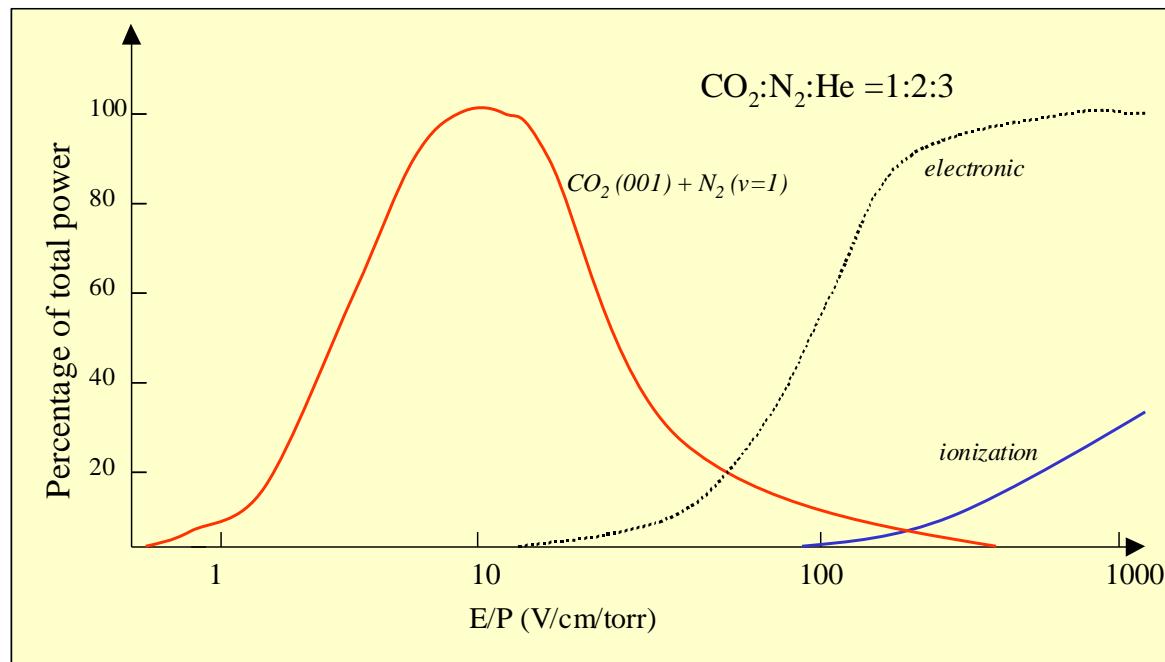
Typical CO₂:N₂:He Gas Ratios Recommended by Laser Manufacturers

CO ₂	N ₂	He	Laser Power Rating W
1	3	17	20
1	1.5	9.3	50
1	1.5	9.3	100
1	1.35	12.5	275
1	8	23	375
1	6.7	30	525
1	2.3	17	1000

11.3 Gas Discharge Phenomena



- Electrons emitted from cathode get accelerated by the electric field
- The energetic electrons excite the vibrational modes of the gas molecule via inelastic collisions

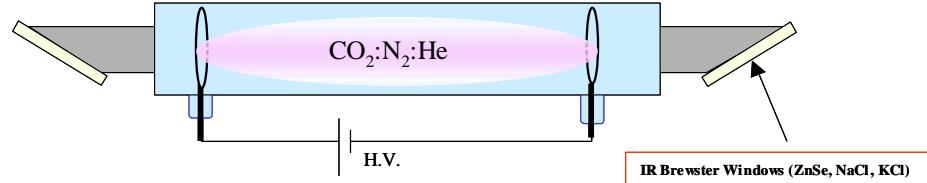


Example:
L=1 meter and P=25 torr
Need V=25 kV for optimum operation

11.4 Specific Types of CO₂ Lasers

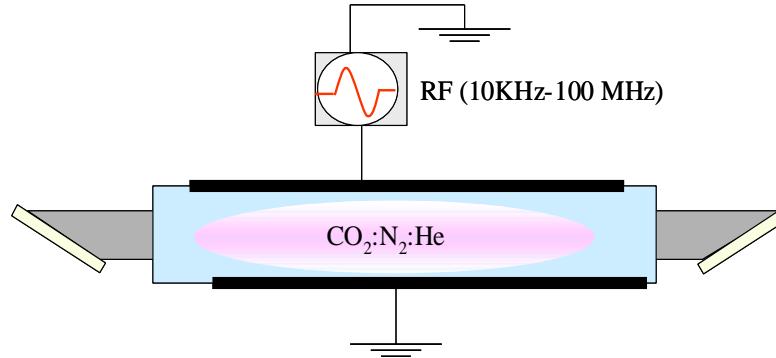
High Power CW Operation

□ DC-Discharge



- Longitudinal discharge (High Voltage: 10-100 kV)
- Pressure: 10-100 torr
- Multistage discharge tubes can be used to produce kilowatts of output power

□ RF-Discharge

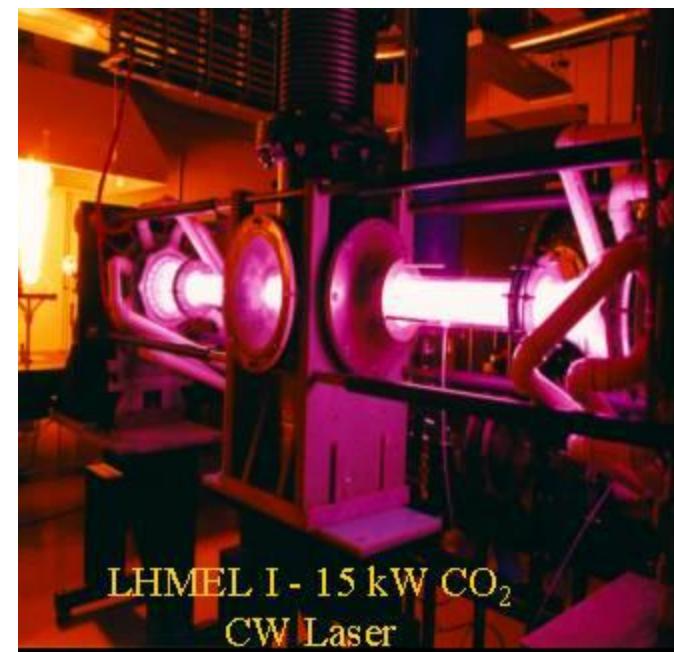
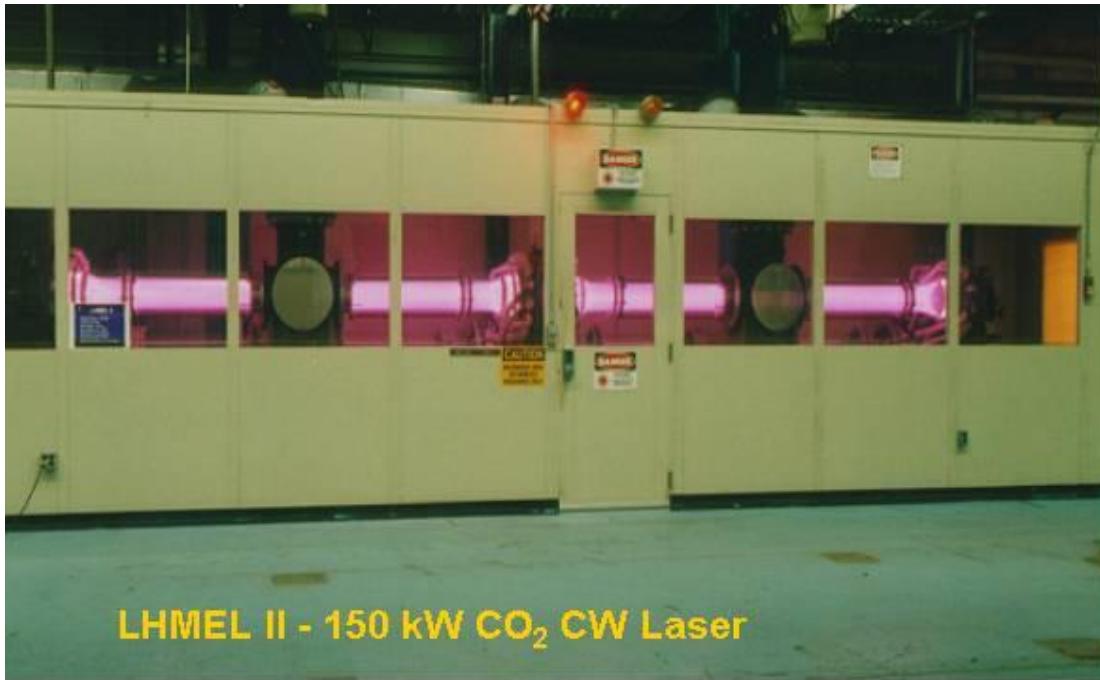


- In practice waveguides are used.
- High discharge stability, high pulsing frequency (up to 100 kHz)
- Expensive RF generator and requires EMI shielding

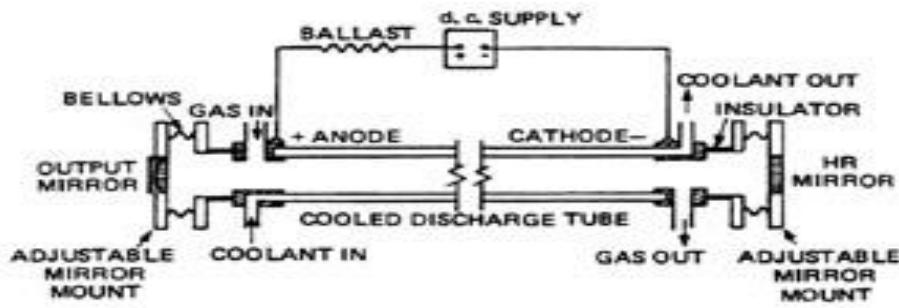
0.2 W/cm in a waveguide laser

Laser Hardened Materials Evaluation Laboratory (LHMEL)

WP-AFB, Dayton, OHIO



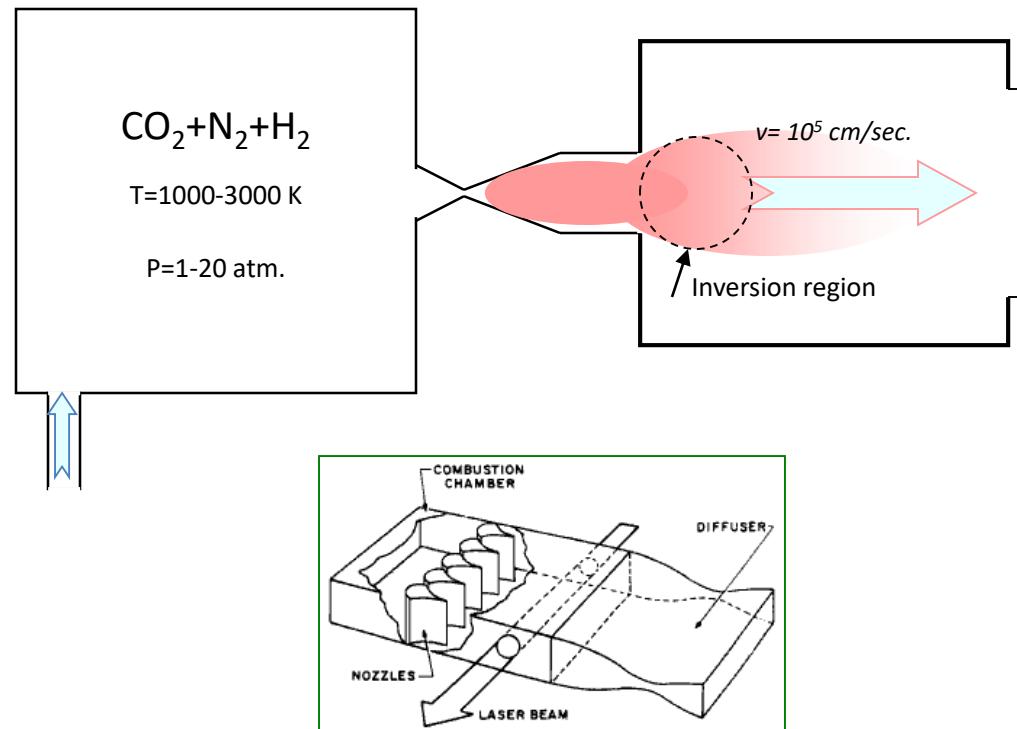
Electric Discharge Coaxial Laser (EDCL)



Gas-Dynamic Lasers

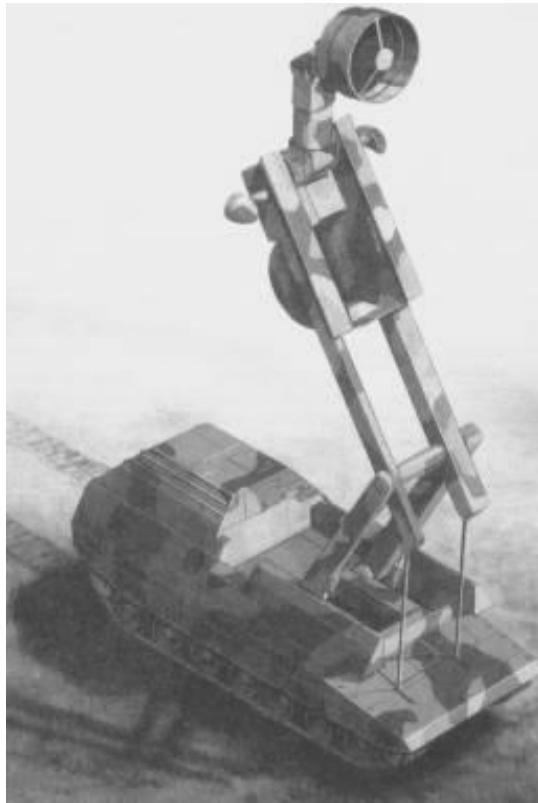
Basov & Oraevskii (1963)

Principle: Population inversion by rapid expansion (supersonic flow) of a super-heated gas



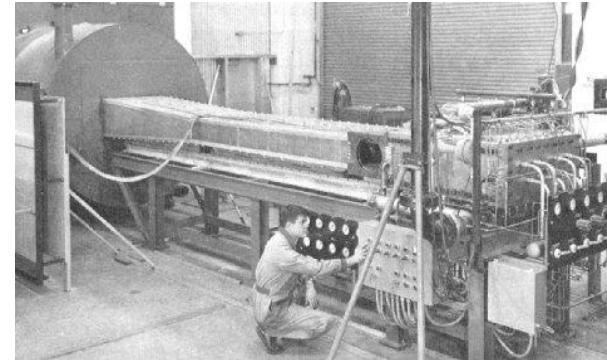
- cw powers up to 1 MW have been obtained from gas-dynamic CO_2 lasers !!

Gas-Dynamic Lasers

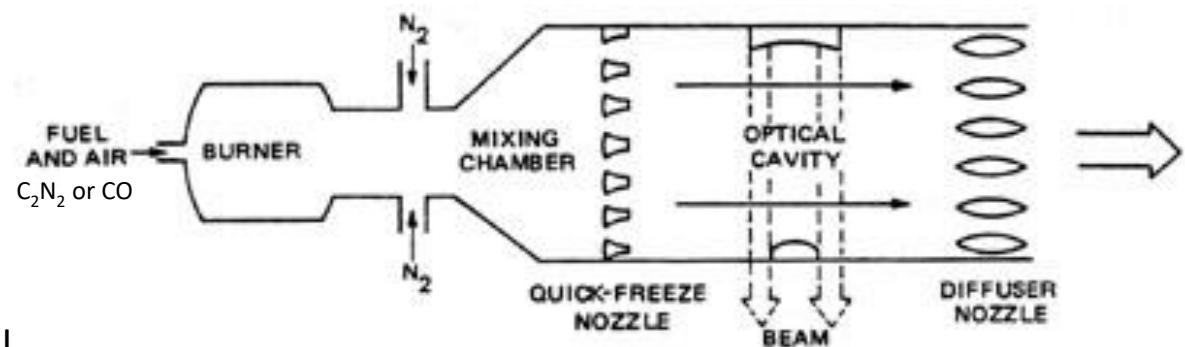


HELEX

High Energy Laser Experimental
Germany, 1970's

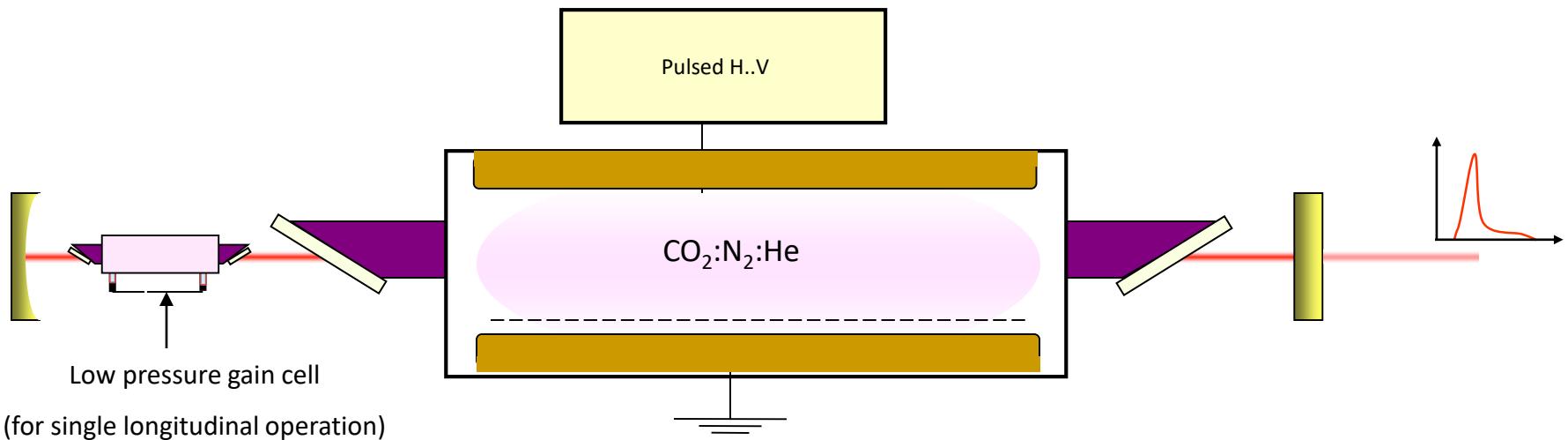


Large scale 135 Kilowatt gasdynamic laser at Avco Everett Research Lab.



•Pulsed CO₂ Lasers

Most Common: Transversely Excited Atmospheric (TEA) CO₂ Lasers



- Flowing or sealed systems
- Pulsewidths from 50 ns to 300 ns
- Repetition rates: 1Hz. to 1 kHz.
- Pulse energy: 50 mJ to 10 J (amplified)

Excimer (Exciplex) Lasers

Nikolai Basov*, V. A. Danilychev and Yu. M. Popov, at the Lebedev Physical Institute

Applications: lithography, micromachining and eye surgery

Molecules exist only in the excited state

(Excimer=Excited-Dimer) or (Exciplex= Exciated-Complex)

XeCl* 308 nm

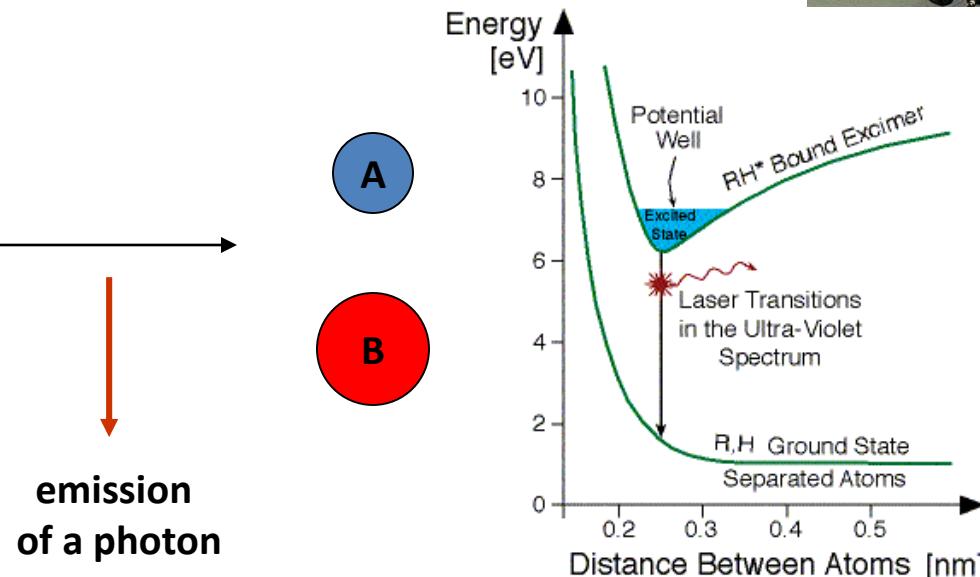
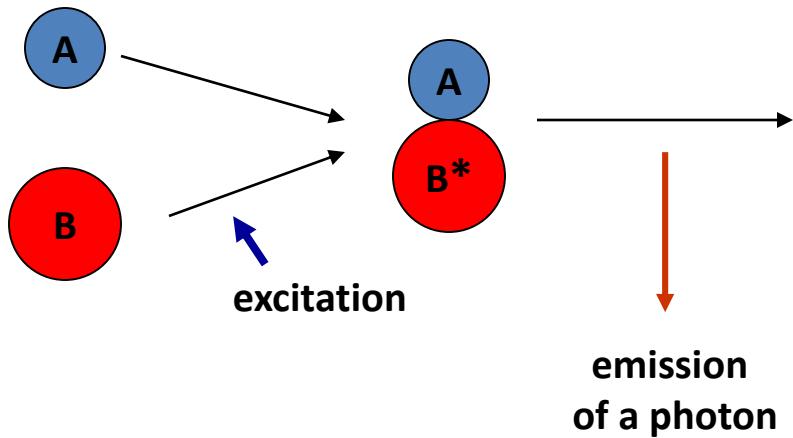
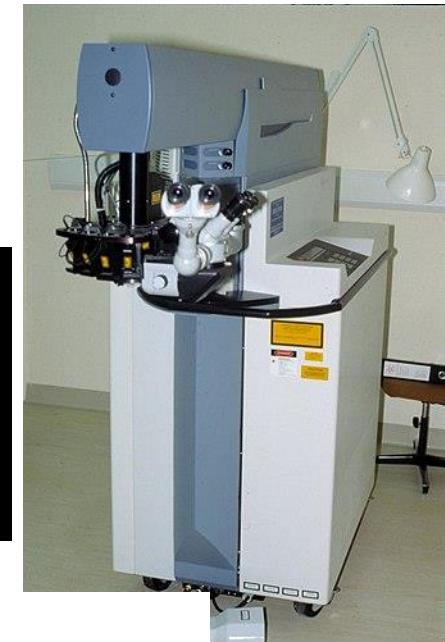
KrF* 248 nm

ArF* 193 nm

F₂* 156 nm



Pulsed, Typically 10-50 ns, 5-20 mJ



Excimer Lasers



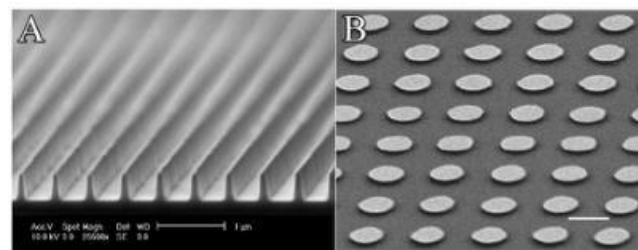
Eye surgery

Lithography



(Cymer Inc.)

ANDY_GEC2009

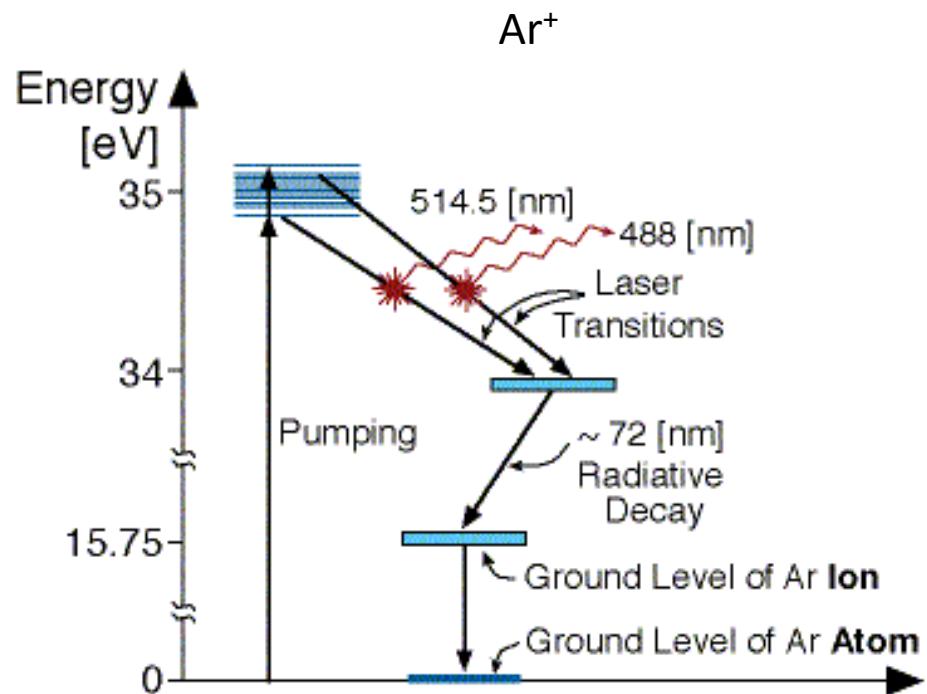
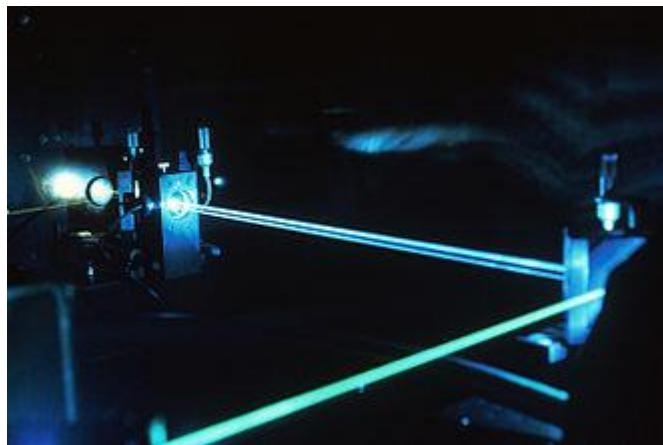


(www.spie.org)

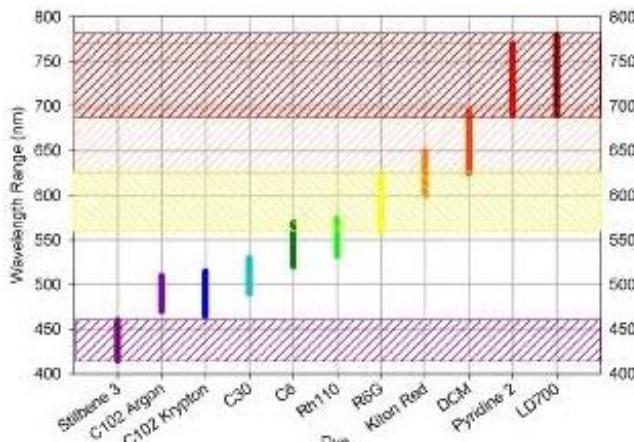
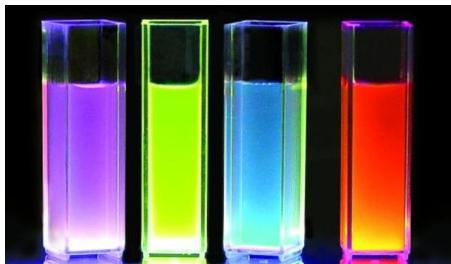
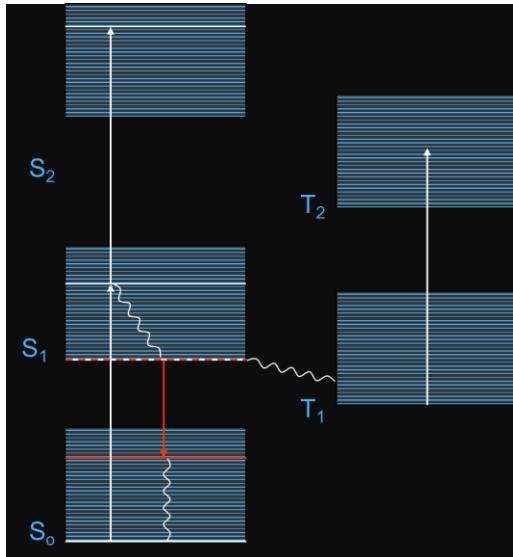
University of Michigan
Institute for Plasma Science & Engr.

Argon Ion Laser

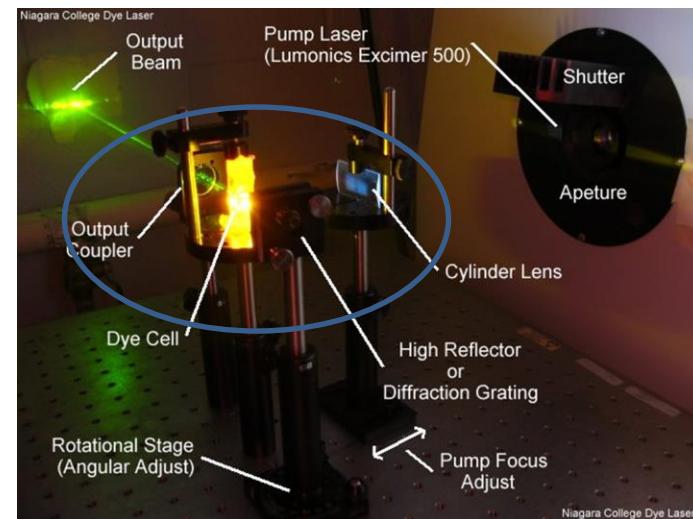
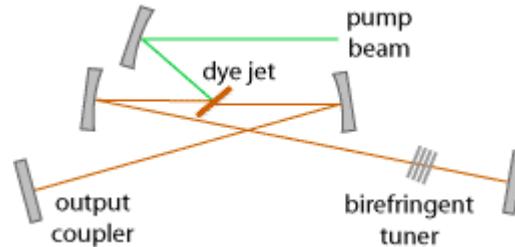
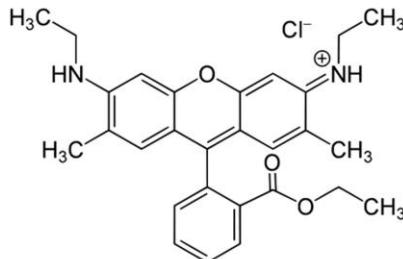
488 and 514 nm



Organic Dye Lasers



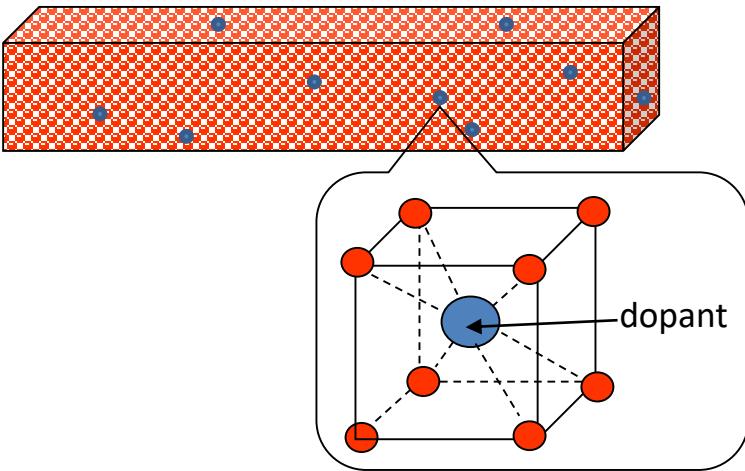
Example: Rhodamine 6G



Solid-State Lasers

- The lasing atoms (ions) are fixed in a solid (crystal, glass).
- Solid-state lasers can operate in continuous (cw) or various pulsed modes.
- The active ions are most commonly either a **rare-earth** or **transition metal** elements

host crystal



Period	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
1	H																	He
2	Li	Be																Ne
3	Na	Mg																Ar
4	K	Ca	Sc	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr	
5	Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sb	Te	I	Xe	
6	Cs	Ba	La	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	
7	Fr	Ra	Ac	Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg	Cn	Uut	Uup	Uuh	Uus	Uuo	
*Lanthanides																		
**Actinides																		

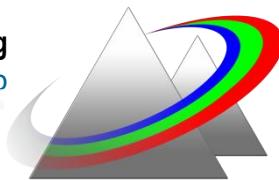
Legend:

- Non Metals
- Noble Gases
- Alkali Metals
- Metalloids
- Alkaline Metals
- Halogens
- Transition Metals
- Rare Earth Elements
- Other Metals

Examples:

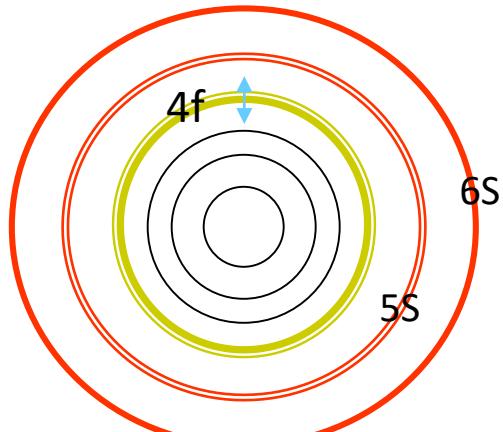
- (a) Nd³⁺ :YAG $\lambda = 1.064 \text{ } \mu\text{m}, 1.331 \text{ } \mu\text{m}$
- (b) Nd³⁺ :glass $\lambda = 1.062 \text{ } \mu\text{m}$ (silicate glass), $\lambda = 1.080 \text{ } \mu\text{m}$ (fused silica)
- (d) Hm³⁺ :YAG, Tm³⁺ :YAG $\lambda = 2.1 \text{ } \mu\text{m}$
- (e) Yb³⁺ : YAG, $\lambda = 1.03-1.05 \text{ } \mu\text{m}$
- (f) Ti³⁺ :sapphire, $\lambda = 0.7 - 1.1 \text{ } \mu\text{m}$
- (g) Fe²⁺ :ZnSe $\lambda = 3.7 - 5.5 \text{ } \mu\text{m}$

The 4f-4f transitions in Rare-Earths Ions:



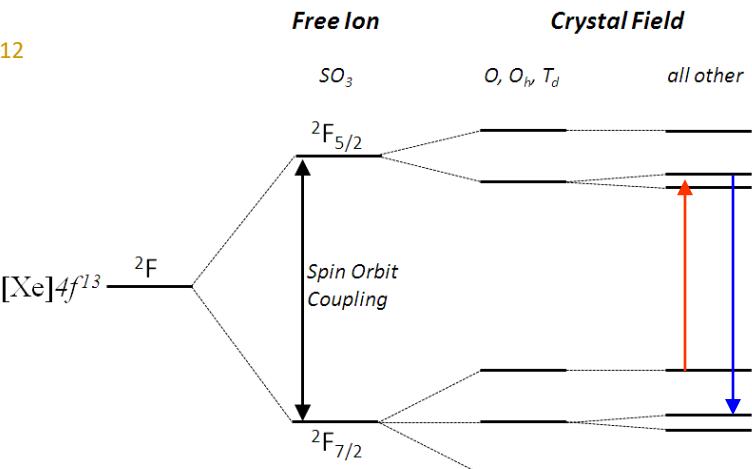
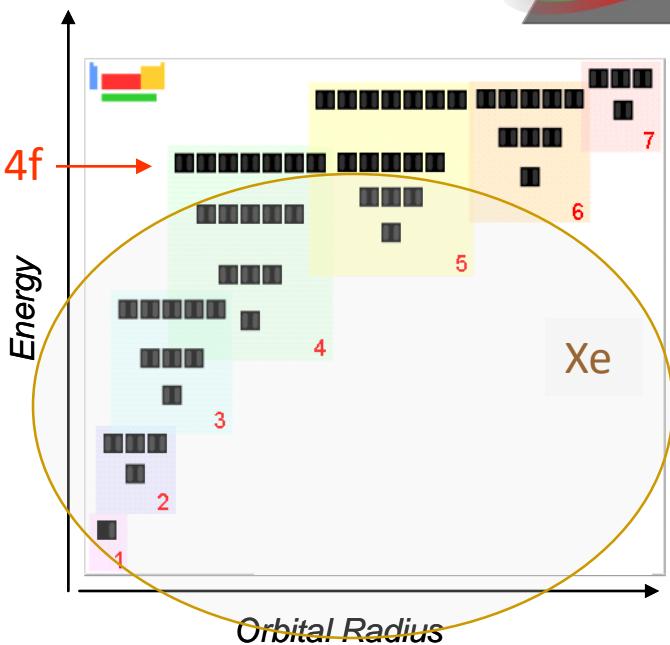
1A	2A	8B										1B	2B	3A	4A	5A	6A	7A	8A	
1 H Hydrogen 1.00994	2 He Helium 4.00260																			
3 Li Lithium 6.941	4 Be Beryllium 9.01218	5 B Boron 10.811	6 C Carbon 12.011	7 N Nitrogen 14.067	8 O Oxygen 15.9994	9 F Fluorine 18.998403	10 Ne Neon 20.1797													
11 Na Sodium 22.98977	12 Mg Magnesium 24.305	13 Al Aluminum 26.98154	14 Si Silicon 28.0855	15 P Phosphorus 30.97376	16 S Sulfur 32.066	17 Cl Chlorine 35.4527	18 Ar Argon 39.948													
19 K Potassium 39.0983	20 Ca Calcium 40.078	21 Sc Scandium 44.9559	22 Ti Titanium 47.88	23 V Vanadium 50.9415	24 Cr Chromium 51.9961	25 Mn Manganese 54.9380	26 Fe Iron 55.847	27 Co Cobalt 58.9332	28 Ni Nickel 58.9324	29 Cu Copper 63.546	30 Zn Zinc 65.39	31 Ga Gallium 69.723	32 Ge Germanium 72.61	33 As Arsenic 74.921	34 Se Selenium 78.95	35 Br Bromine 79.904	36 Kr Krypton 83.80			
37 Rb Rubidium 85.4679	38 Sr Strontium 87.62	39 Y Yttrium 88.9038	40 Zr Zirconium 91.224	41 Nb Niobium 92.9046	42 Mo Molybdenum 95.94	43 Tc Technetium (98)	44 Ru Ruthenium 102.9555	45 Rh Rhodium 106.42	46 Pd Palladium 107.8682	47 Ag Silver 106.42	48 Cd Cadmium 112.411	49 In Indium 114.82	50 Sn Tin 118.710	51 Sb Antimony 121.757	52 Te Tellurium 127.60	53 I Iodine 126.9045	54 Xe Xenon 131.29			
55 Cs Cesium 132.9054	56 Ba Barium 137.327	*La Lanthanide Series 138.9055	57 Hf Hafnium 173.49	72 Ta Tantalum 180.9479	73 W Tungsten 186.207	74 Re Rhenium 190.2	75 Os Osmium 193.85	76 Ir Iridium 192.22	77 Pt Platinum 195.08	78 Au Gold 196.9665	79 Hg Mercury 200.59	80 Tl Thallium 204.3833	82 Pb Lead 207.2	83 Bi Bismuth 208.9804	84 Po Polonium (209)	85 At Astatine (210)	86 Rn Rodon (222)			
87 Fr Francium (223)	88 Ra Radium (226)	+Ac Actinium (227)	104 Rf Rutherfordium (261)	105 Db Dubnium (262)	106 Sg Seaborgium (263)	107 Bh Bohrium (262)	108 Hs Meitnerium (265)	109 Mt Mendelevium (268)	110	111	112									

* Lanthanide Series	58 Ce Curium 140.115	59 Pr Protactinium 140.0777	60 Nd Neodymium 144.24	61 Pm Promethium (145)	62 Sm Samarium 150.36	63 Eu Europium 151.965	64 Gd Gadolinium 157.25	65 Tb Terbium 158.9254	66 Dy Dysprosium 162.20	67 Ho Holmium 164.9303	68 Er Erbium 167.26	69 Tm Thulium 168.9342	70 Yb Ytterbium 173.0	71 Lu Lutetium 174.967					
† Actinide Series	90 Th Thorium 232.0381	91 Pa Protactinium 231.0359	92 U Uranium 238.0289	93 Np Neptunium 237.048	94 Pu Plutonium (244)	95 Am Americium (243)	96 Cm Curium (247)	97 Bk Berkelium (247)	98 Cf Californium (251)	99 Es Fermium (257)	100 Fm Mendelevium (258)	101 Md Moscovium (259)	102 No Nobelium (259)	103 Lr Livermorium (260)					



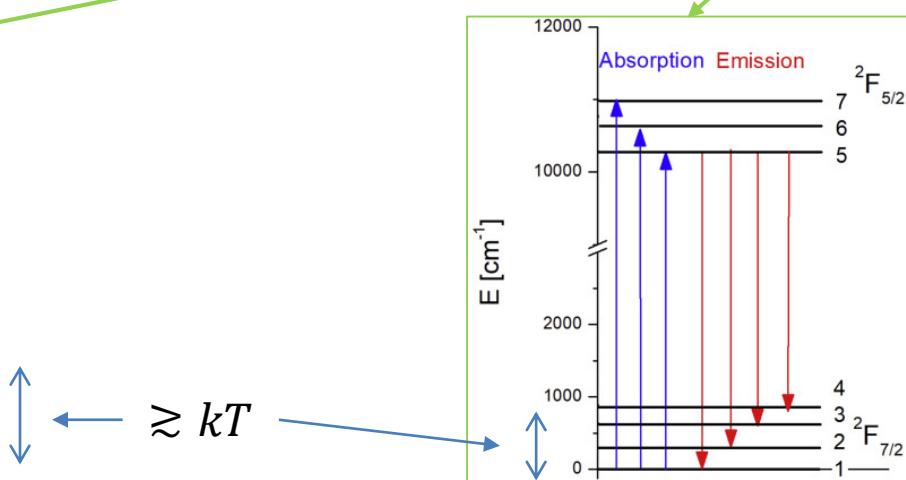
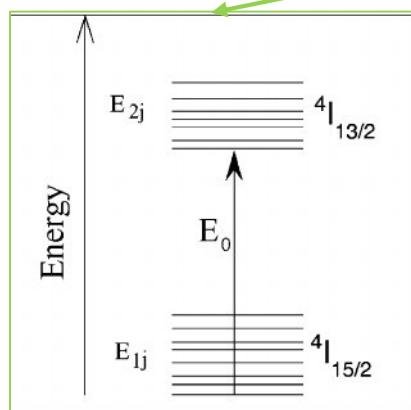
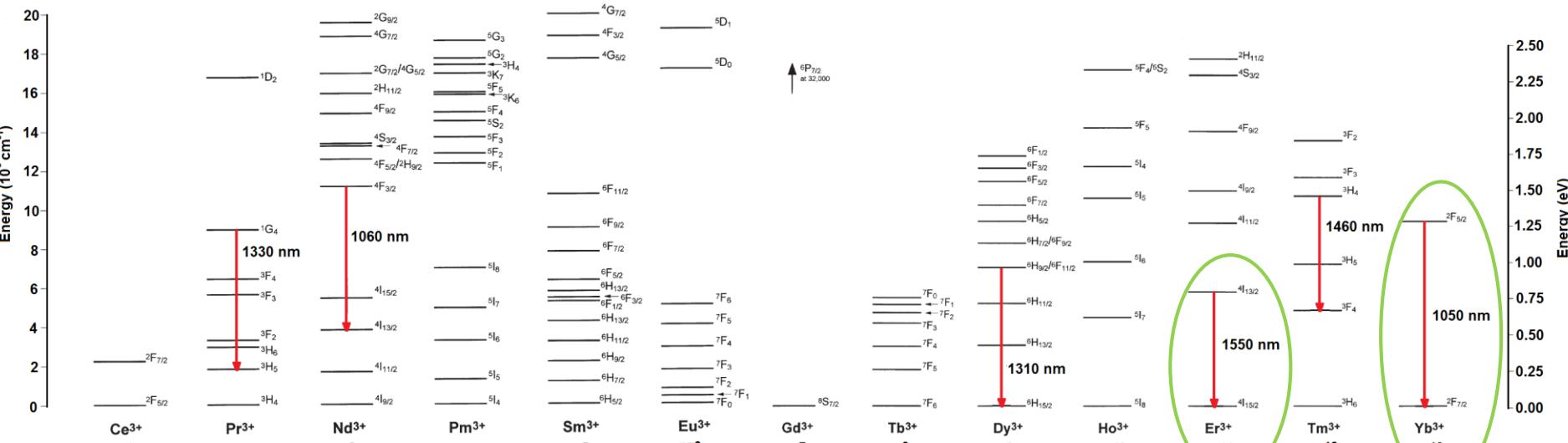
$$2S+1L_J$$

$$\text{Degeneracy: } g = 2J + 1$$



Rare-Earth Ion Doped Lasers

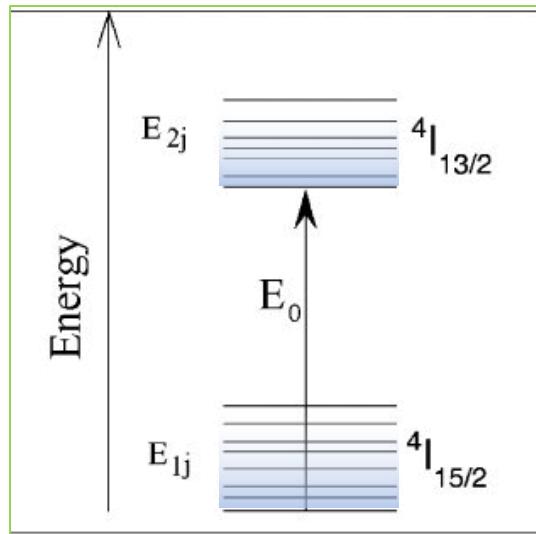
Lanthanides



Quasi Four-Level Lasers

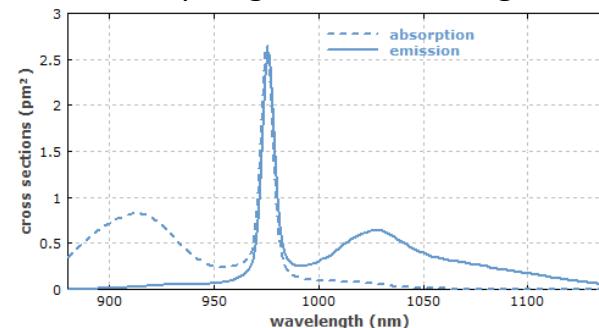
McCumber Relation

D. E. McCumber, "Einstein relations connecting broadband emission and absorption spectra", Phys. Rev. 136 (4A), A954 (1964),

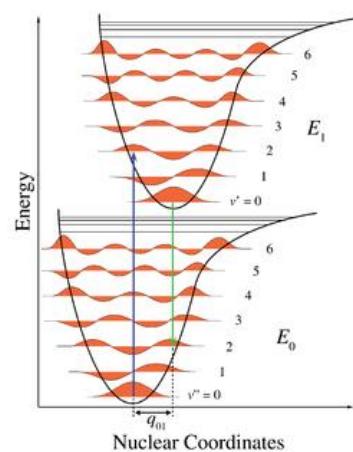


$$\sigma_{\text{abs}}(\nu) = \sigma_{\text{em}}(\nu) \exp\left(\frac{h\nu - E_0}{k_B T}\right)$$

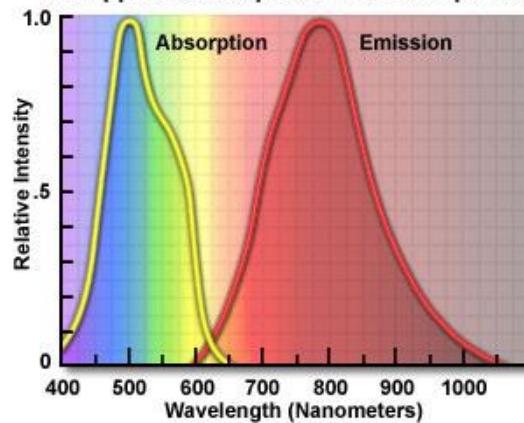
Yb-doped germanosilicate glass



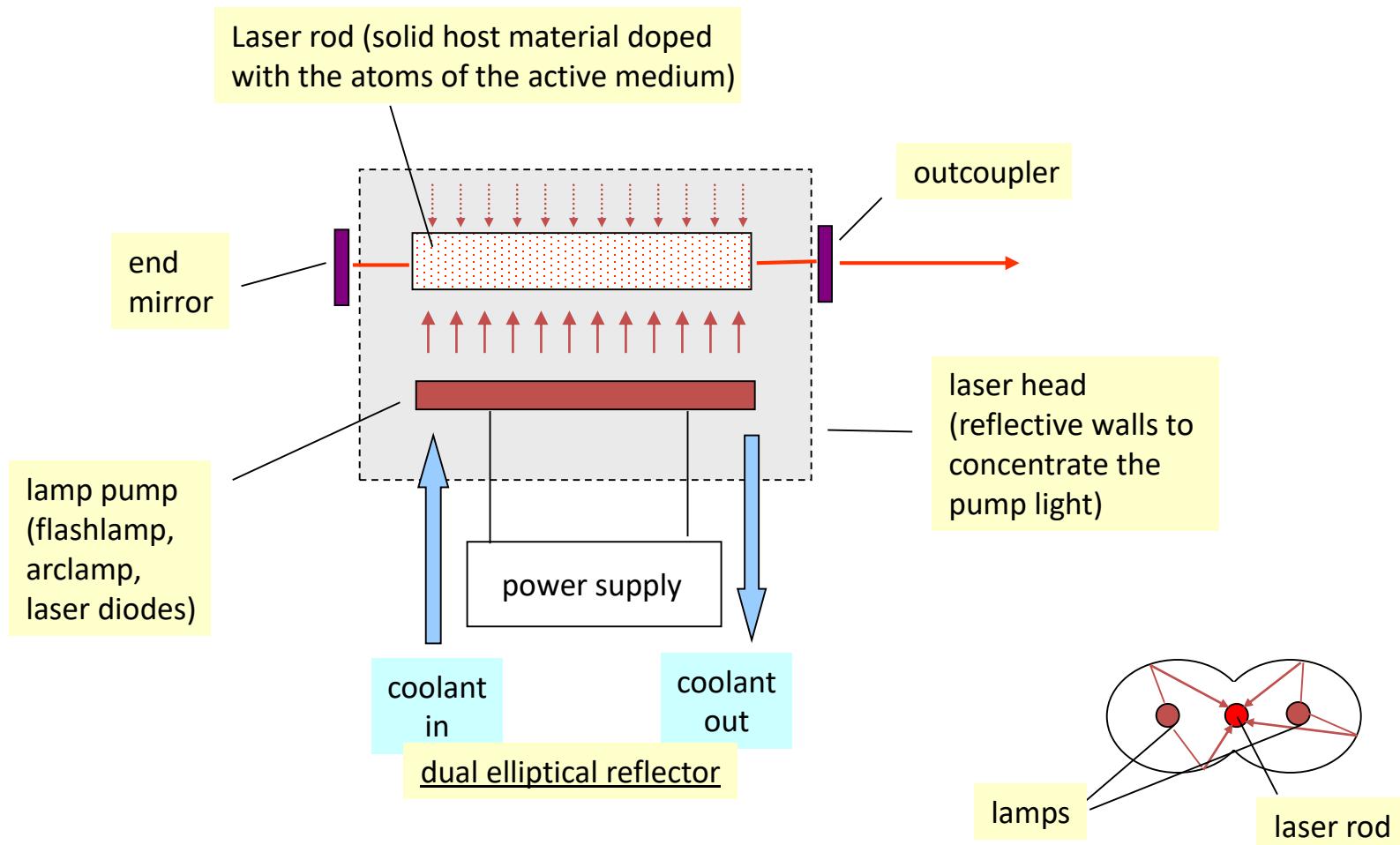
Vibronic Transitions



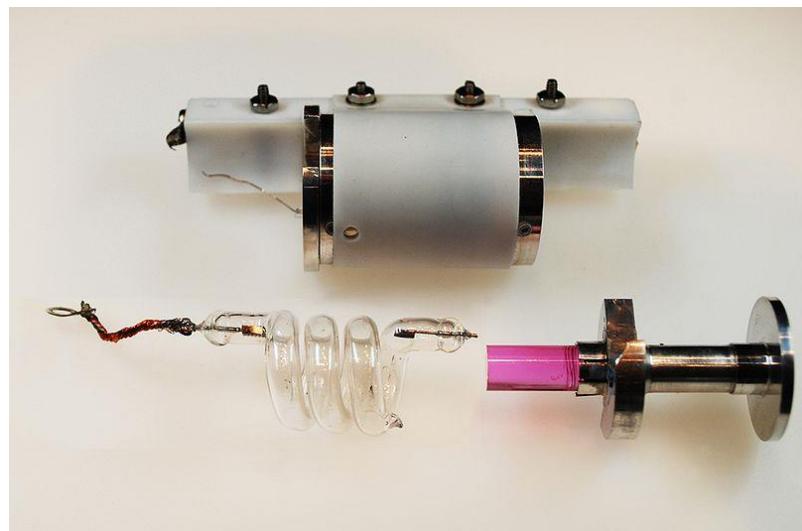
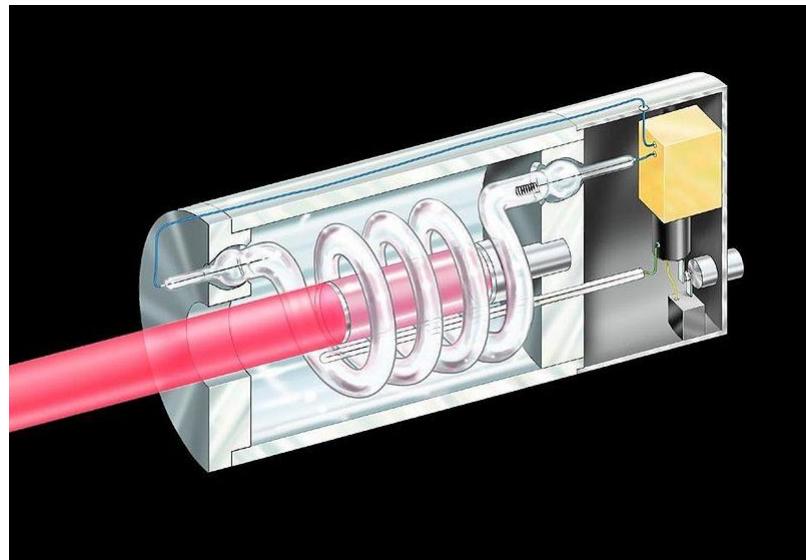
Ti:Sapphire Absorption/Emission Spectra



Layout of early (flash-lamp or arc-lamp pumped) solid-state lasers

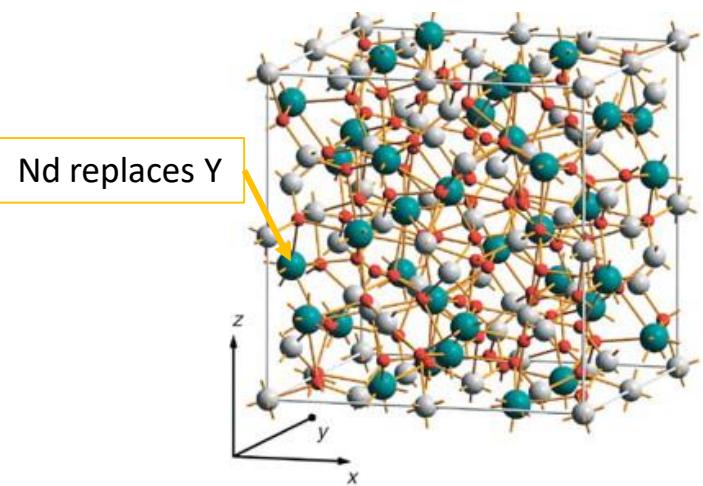


Maiman's Ruby Laser

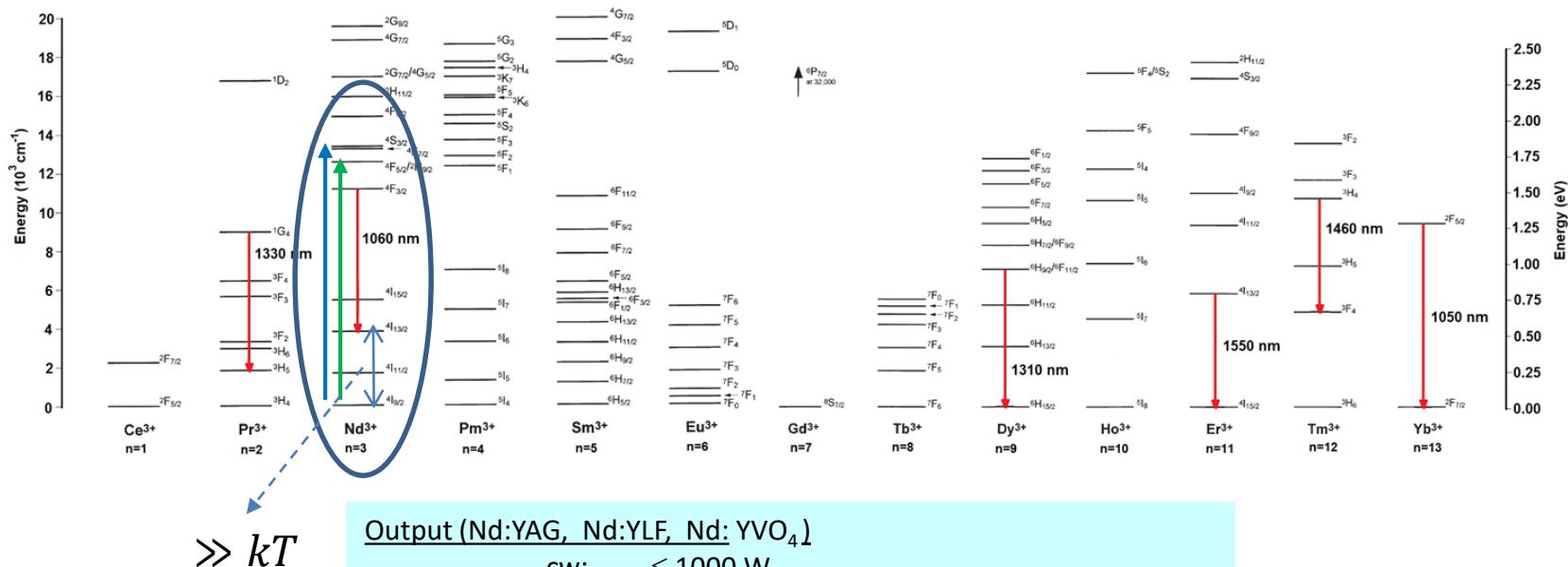
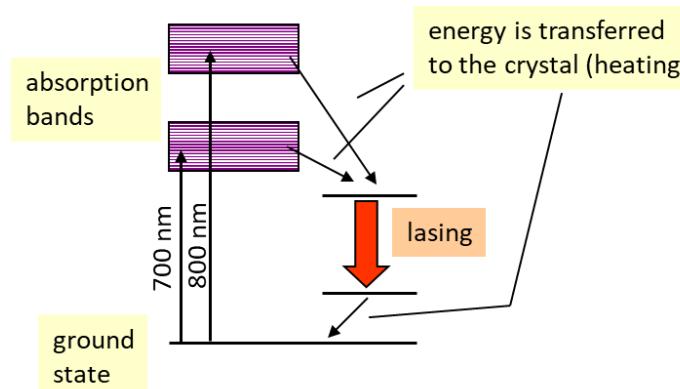


Example: Nd:YAG laser

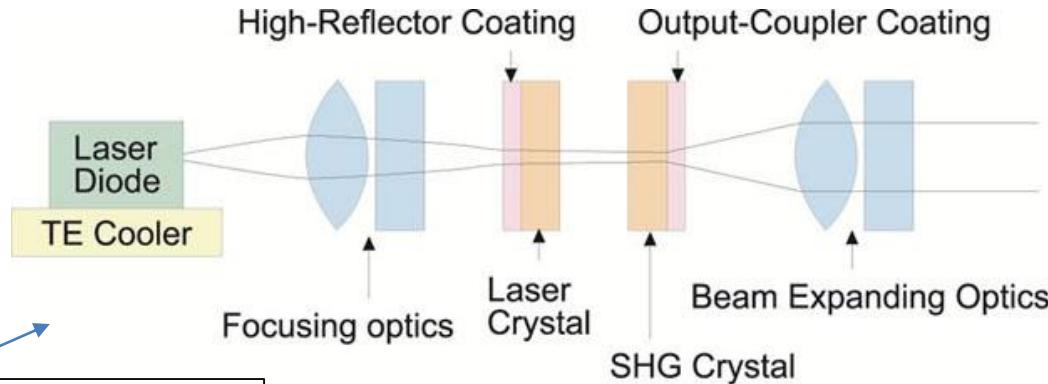
YAG: Yttrium Aluminum Garnet ($\text{Y}_3\text{Al}_5\text{O}_{12}$)



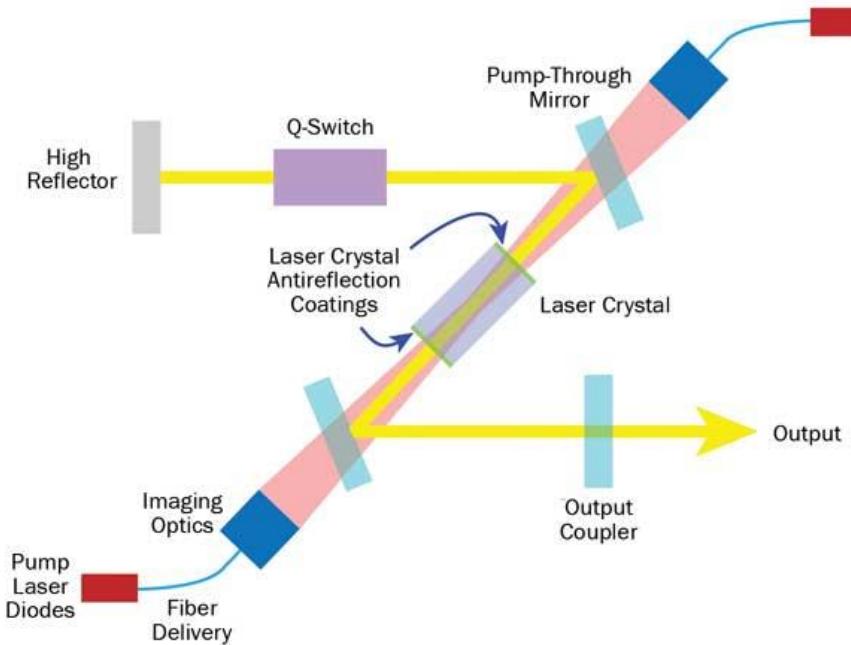
Energy diagram of Nd³⁺:



DPSS : Diode-Pumped Solid-State Laser

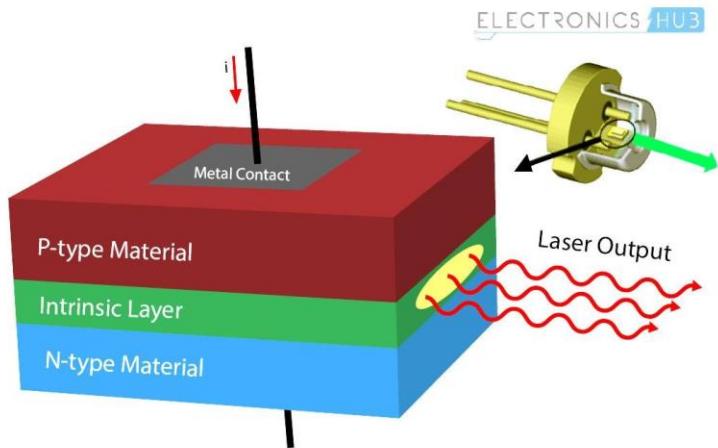


Similar to one used in our Optics Lab



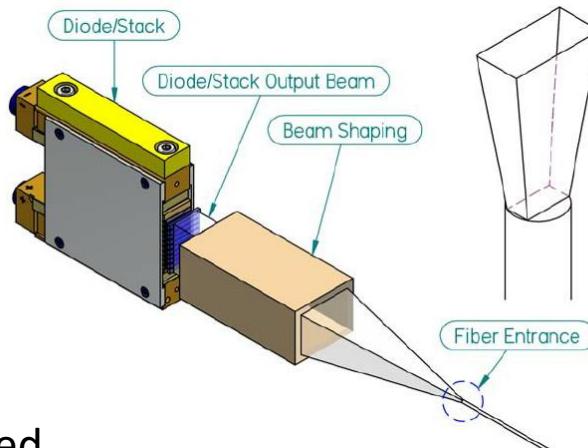
Diode Lasers for Pumping

Semiconductor lasers will be covered in more detail (next lecture)



LASER DIODE CONSTRUCTION

- Efficient (current injection)
- High power
- Designer Wavelength
- Poor Beam Quality
- Broadband (3-5 nm)



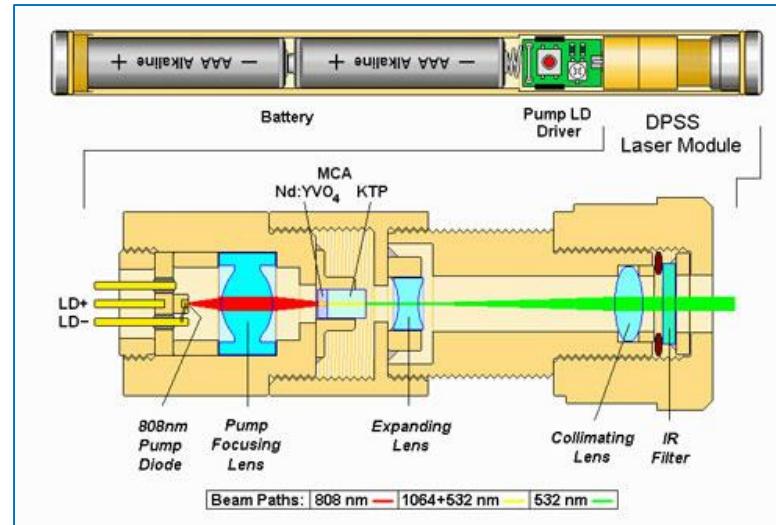
High Power (Diode Bar) Fiber Coupled

DPSS : Diode-Pumped Solid-State Laser

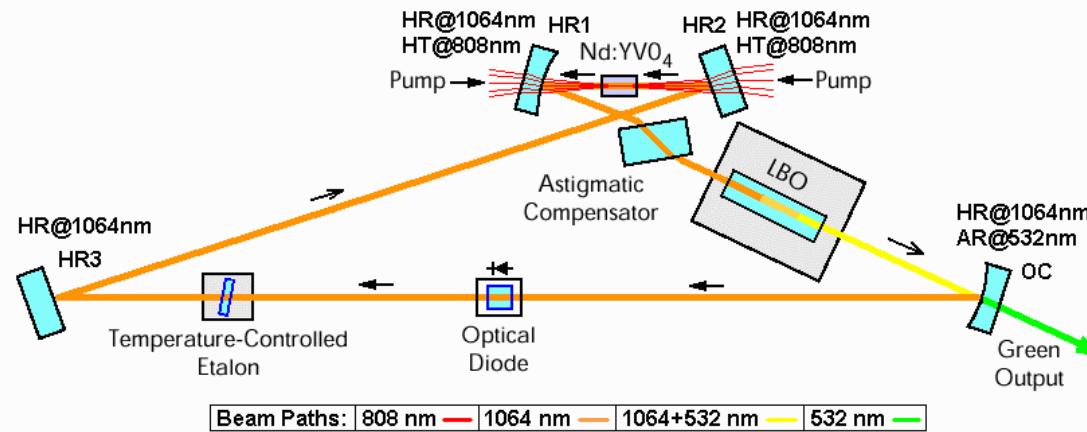
Example Nd:YVO₄ (Vanadate)

From laser pointers (5-10 mW) to 100W lasers

5-10mW
\$20



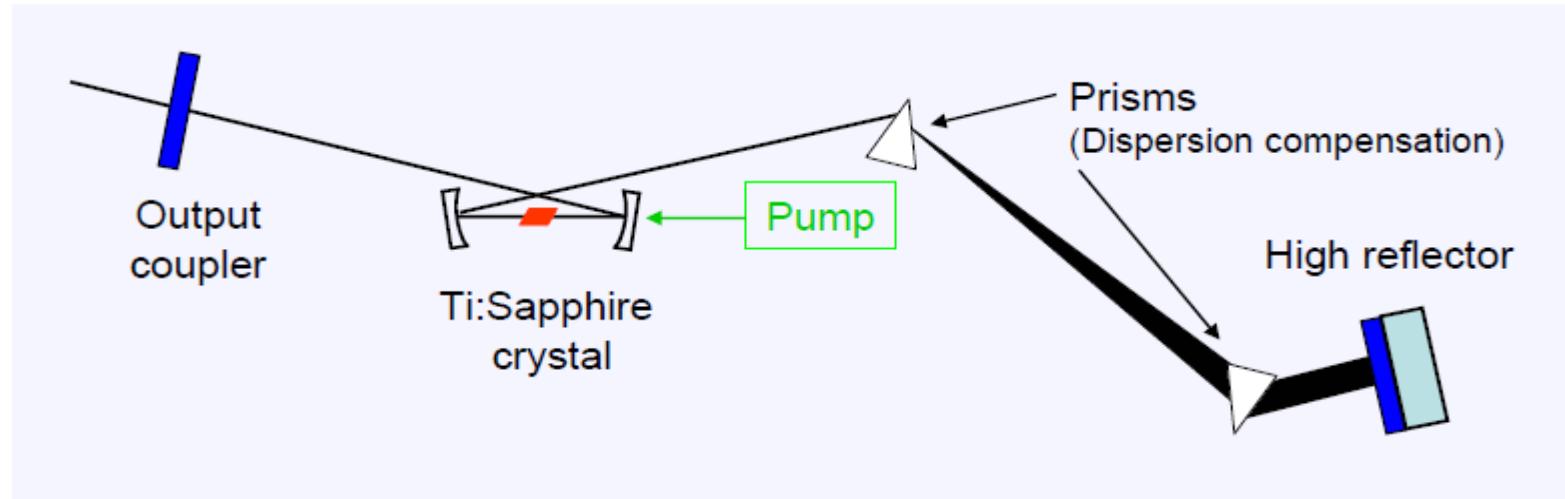
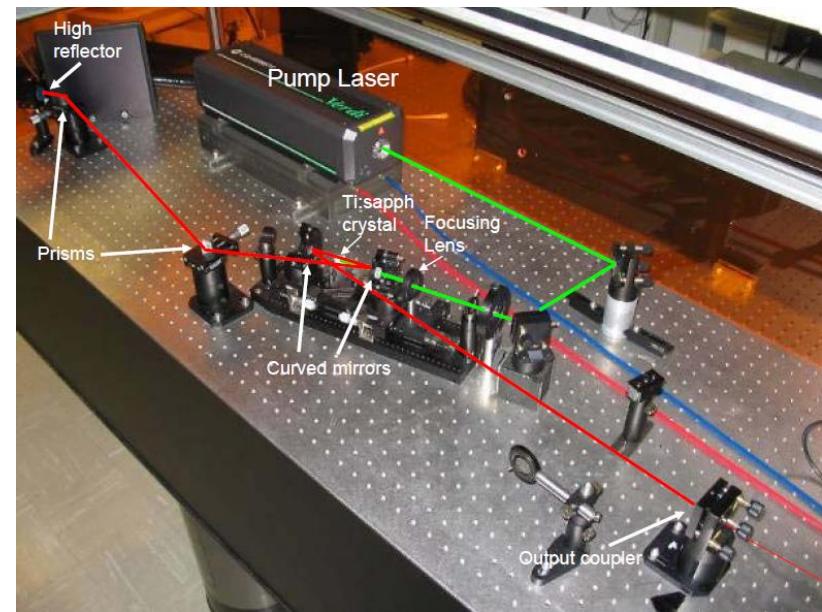
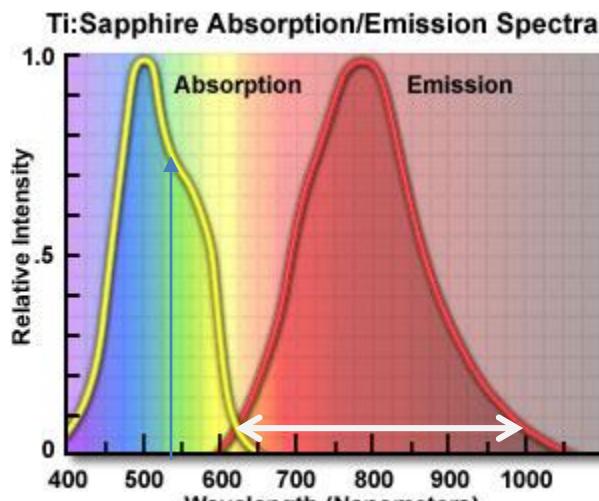
5-10W
\$10k-\$40k



Ring Cavity Resonator of Coherent, Inc. Verdi Green DPSS Laser

Titanium doped sapphire ($\text{Ti}^{3+} : \text{Al}_2\text{O}_3$) laser

The jewel of ultrafast lasers



Historical Progress in Ultrashort Pulses



Nobel Prizes

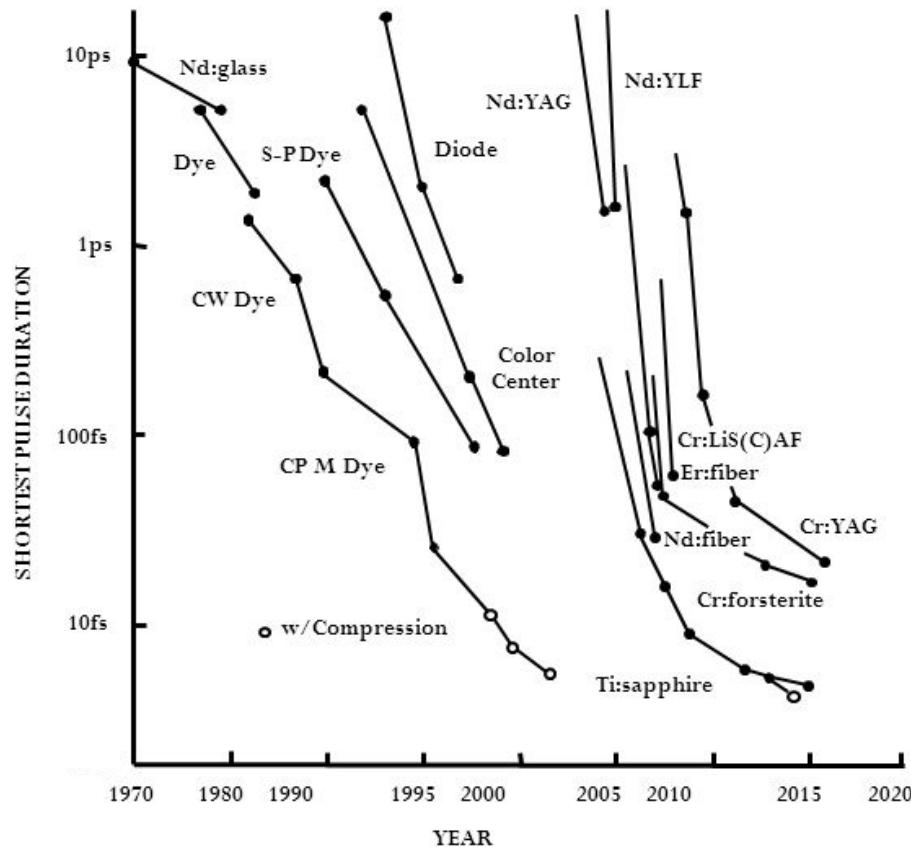
[John L. Hall](#) and [Theodor W. Hänsch](#)"

"for their contribution to the development of laser-based precision spectroscopy, including the optical frequency comb technique" (2005)

[Gérard Mourou](#) and [Donna Strickland](#)

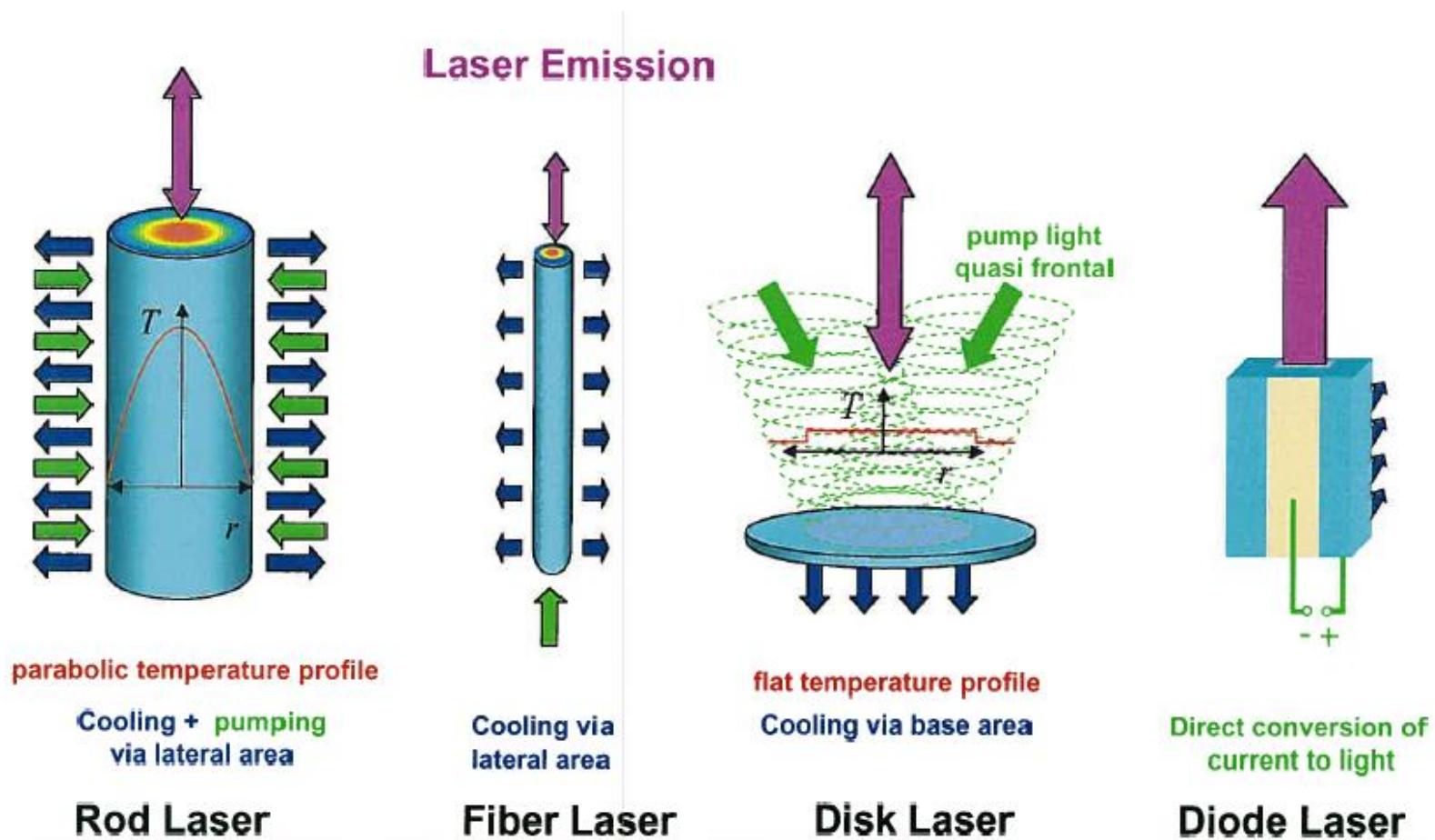
"for their method of generating high-intensity, ultra-short optical pulses" 2018

[Ahmed H. Zewail](#) "for his studies of the transition states of chemical reactions using femtosecond spectroscopy" 1999 (Chemistry)

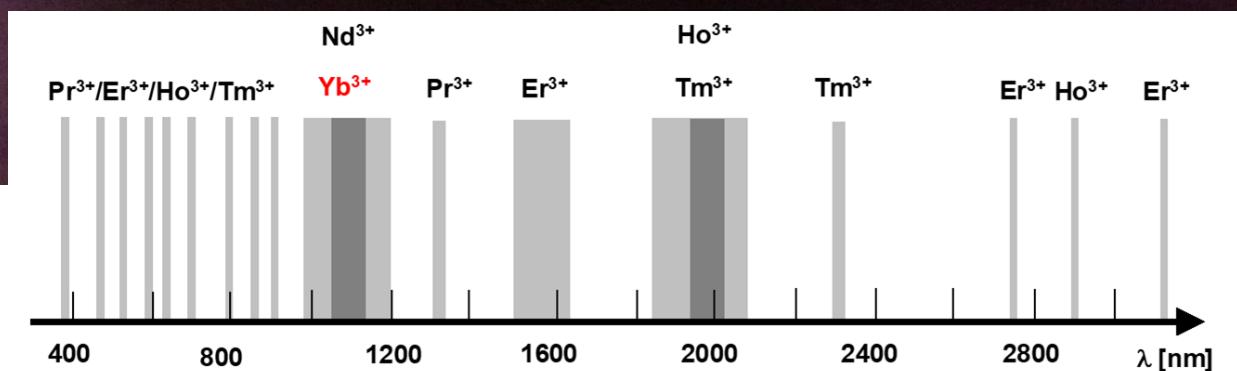
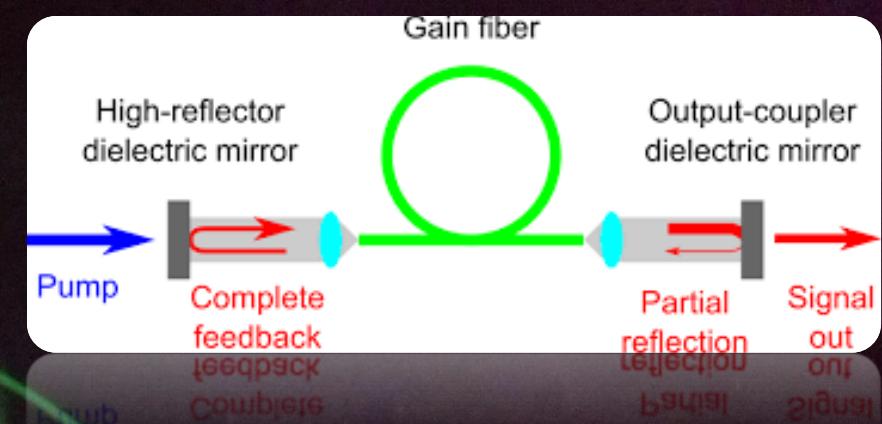


High Power Scaling: Heat is such a nuisance!

Increase surface-to-volume ratio (fibers, disks)



Fiber Lasers



first demonstration of a fiber laser: in the early sixties !

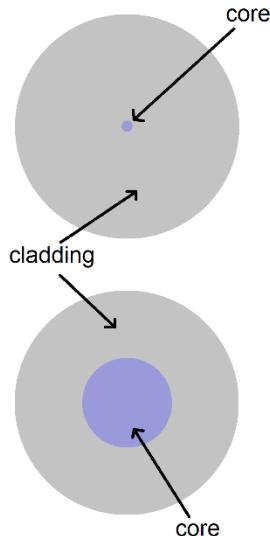
E. Snitzer, "Neodymium glass laser," Proc. of the Third International conference on Solid Lasers, Paris, page 999 (1963).
C.J. Koester and E.Snitzer, "Amplification in a fiber laser," Appl. Opt. 3, 10, 1182 (1964).

Fiber Lasers

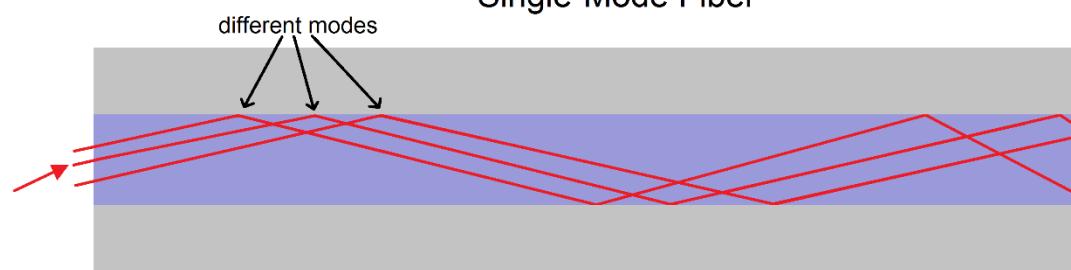
Single-Mode Fiber

6 μm core / 125 μm cladding

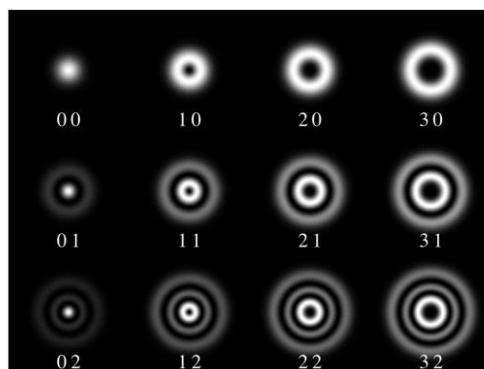
- + High Beam Quality
- Lower Power Pumping
- Expensive Pumping



Single-Mode Fiber



Multimode Fiber

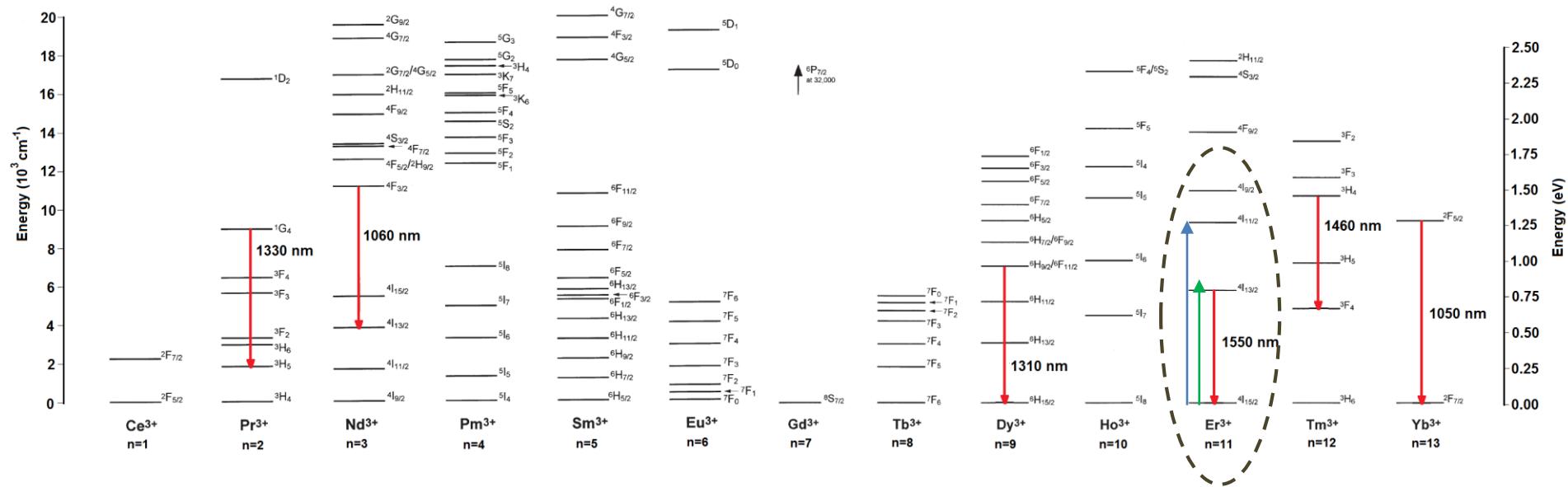


Optical Fiber Modes

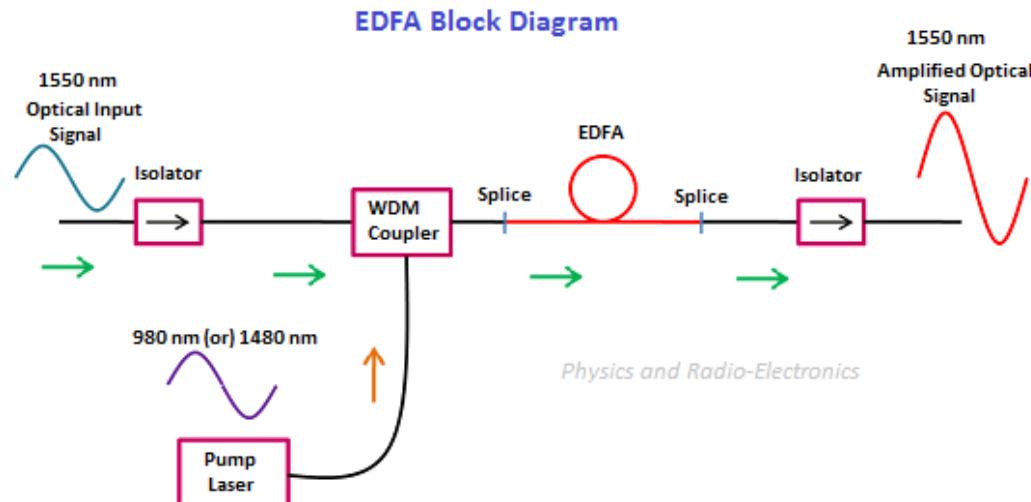
Graphics: courtesy of Colin Diehl & Jered Richter

Example: Erbium-Doped fiber Lasers

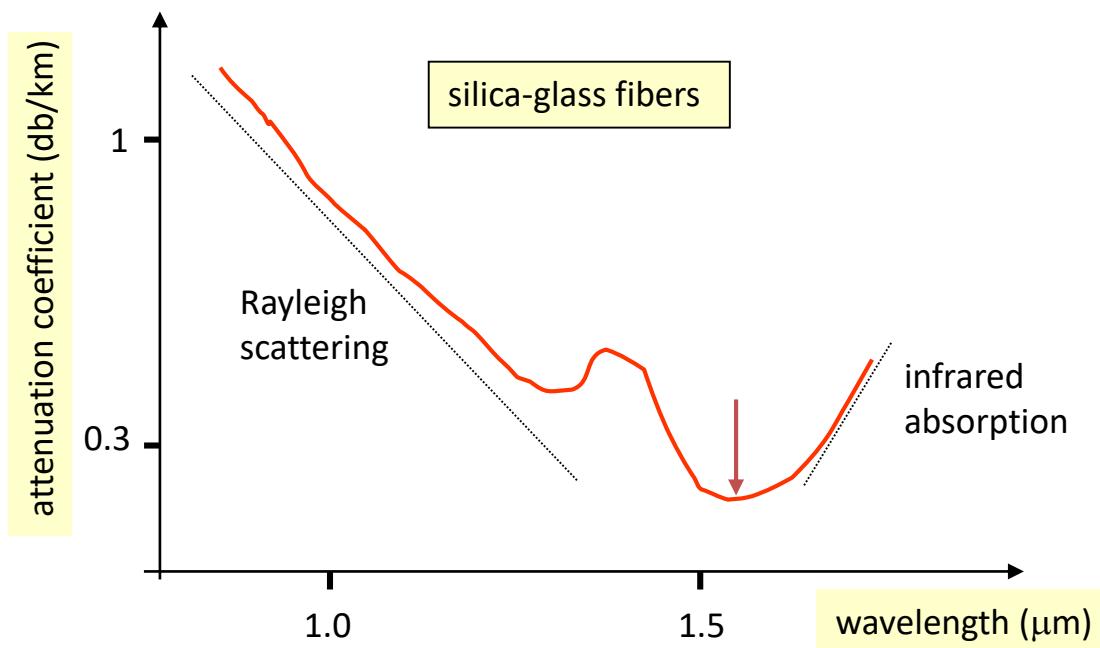
The wavelength of about 1550 nm is particularly interesting for applications in telecommunication.



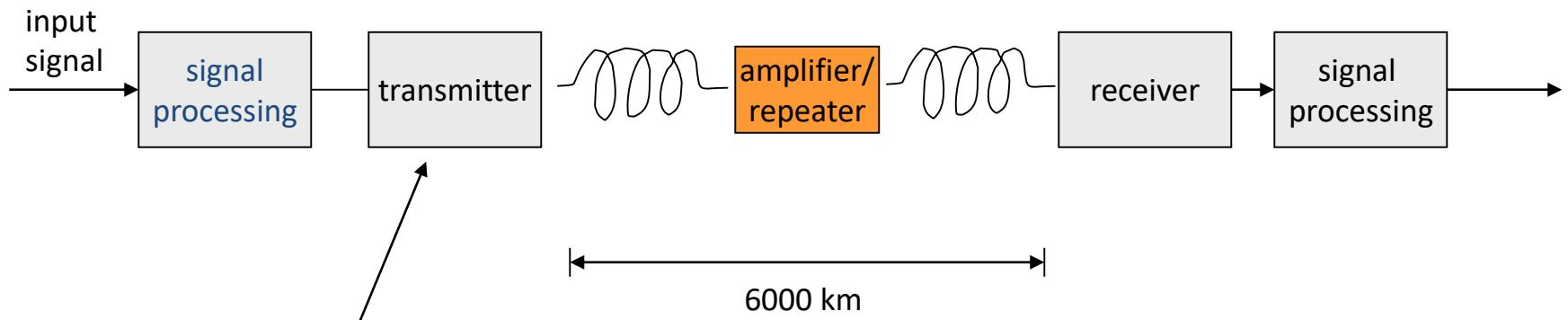
EDFA: Erbium Doped Fiber Amplifier



Fiber-optic Communications



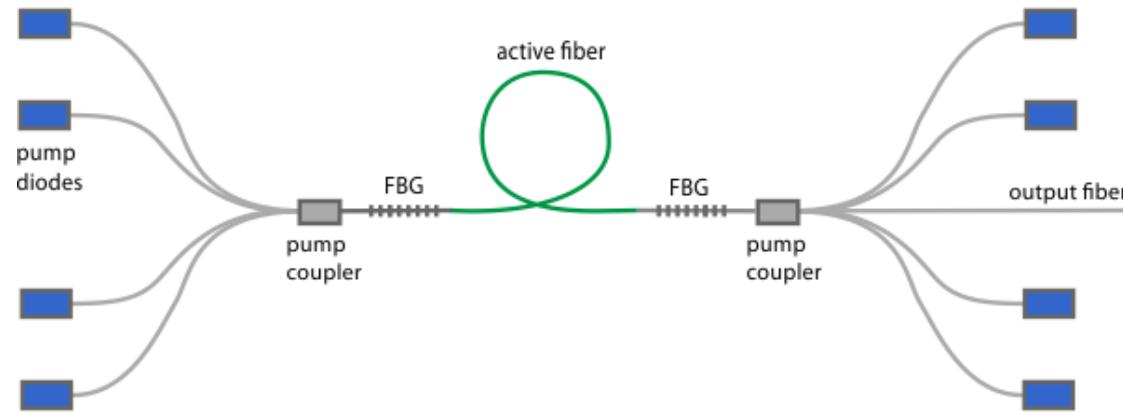
Fiber transmission line



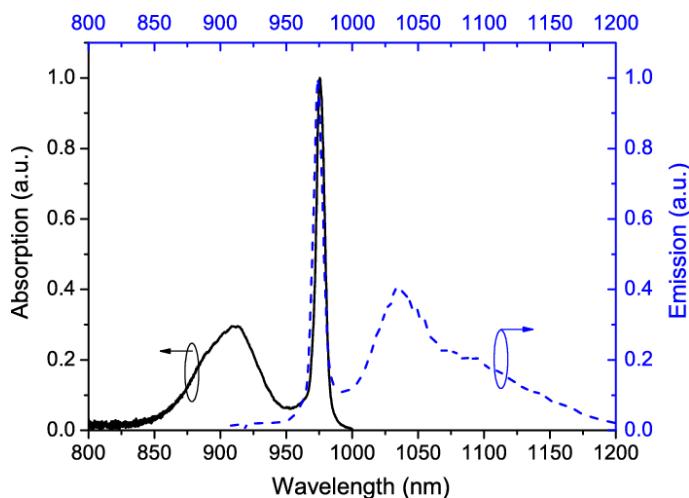
InGaAsP
diode laser

- transatlantic US - UK
- 80000 simultaneous voice channels
- repeaters 100 km apart

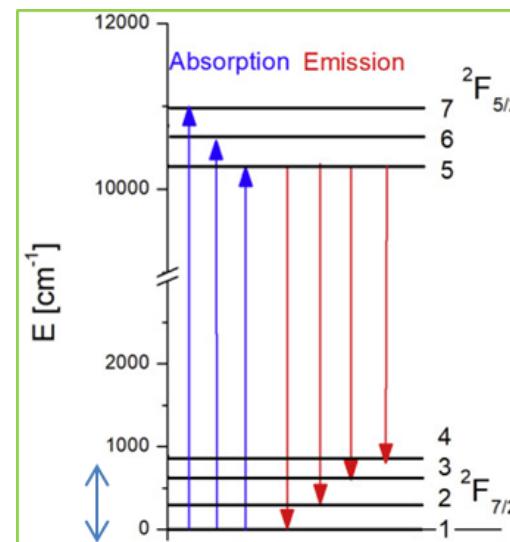
High Power Fiber Lasers



Mainly: Yb Silica Fiber Lasers



Diode Pumped at 940-980 nm



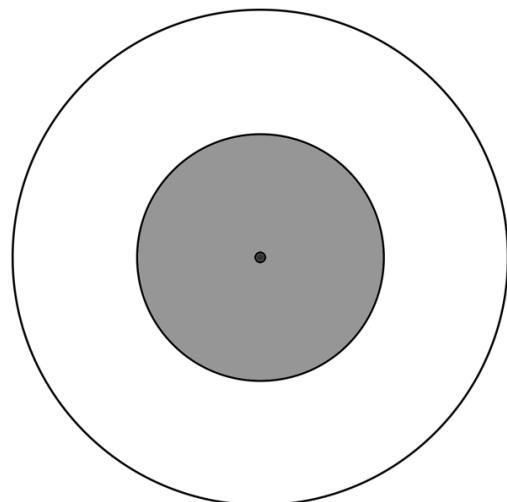
Laser: 1020-1050 nm

High Power Fiber Lasers

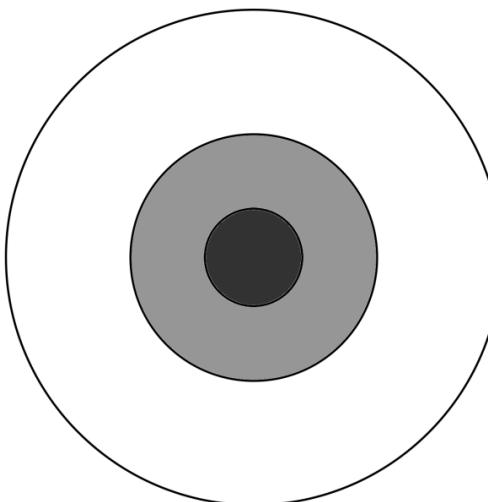
Double-Clad Fiber

- Laser light propagates in single-mode core
- Pump light propagates in inner cladding

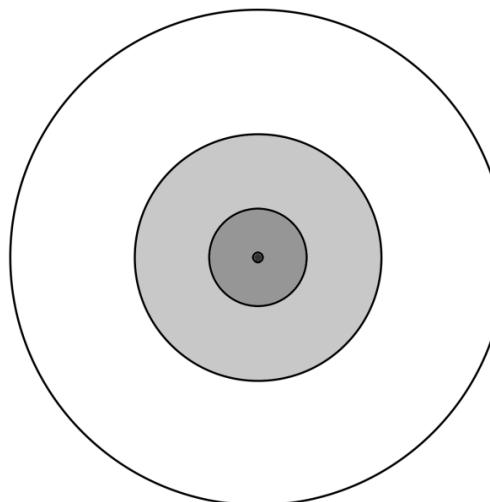
Single-Mode Fiber



Multimode Fiber



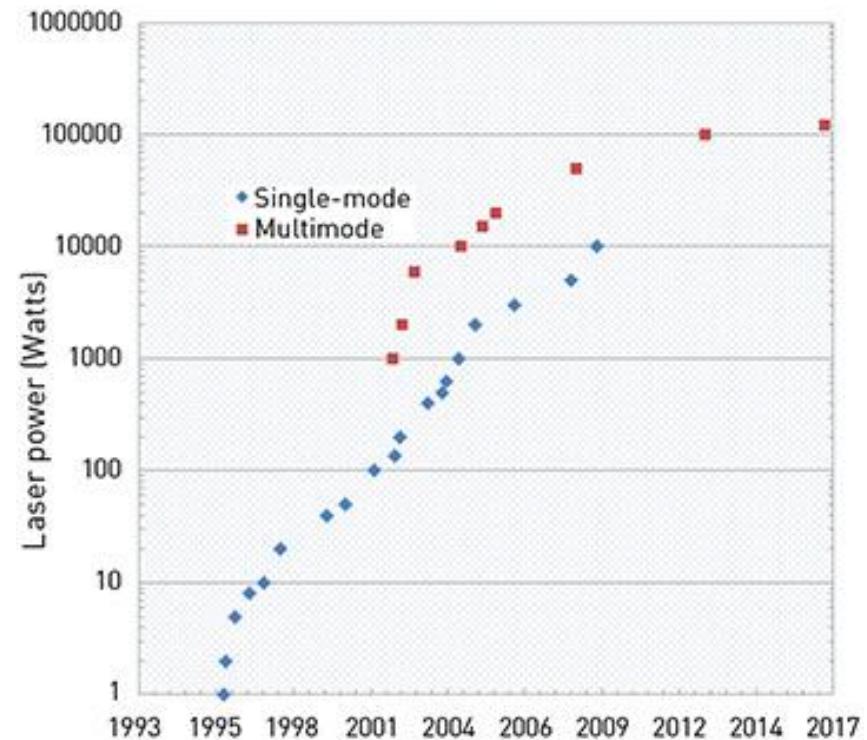
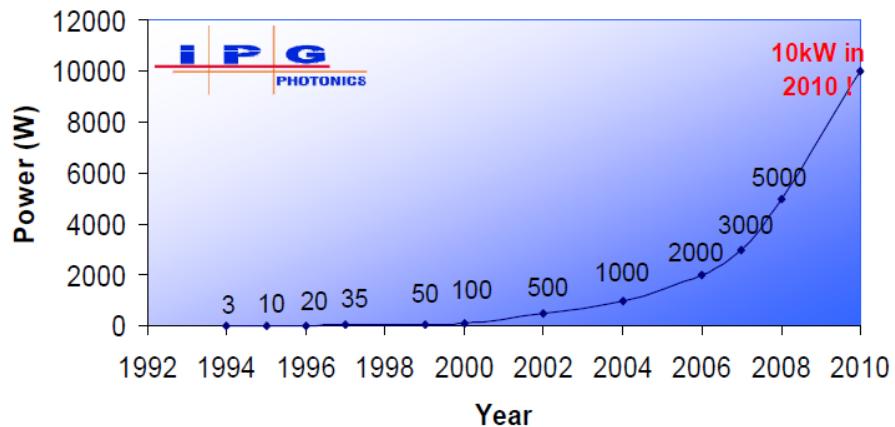
Double-Clad Fiber



	= Core
	= Inner Cladding
	= Outer Cladding
	= Coating

Growth of Yb:HPFL SM

(near diffraction limited)



100 kW (current record)!



IPG Fiber Lasers



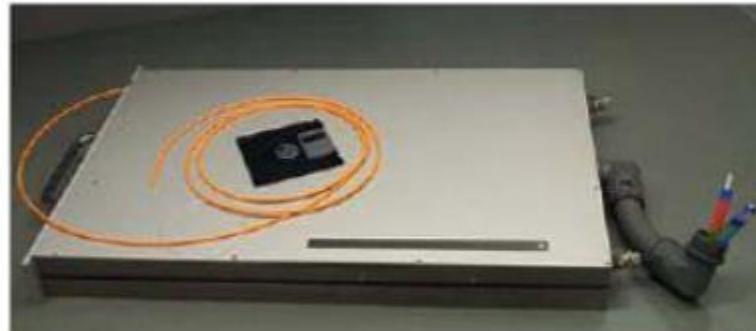
A single module can supply:

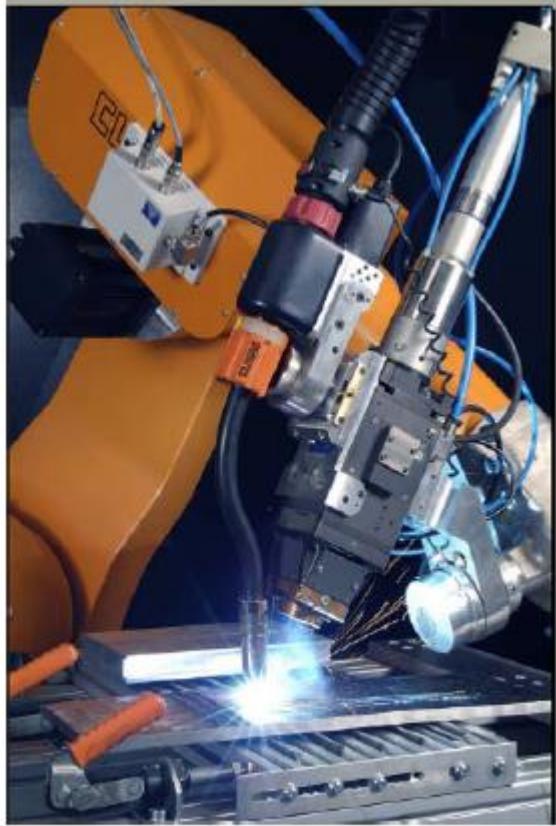
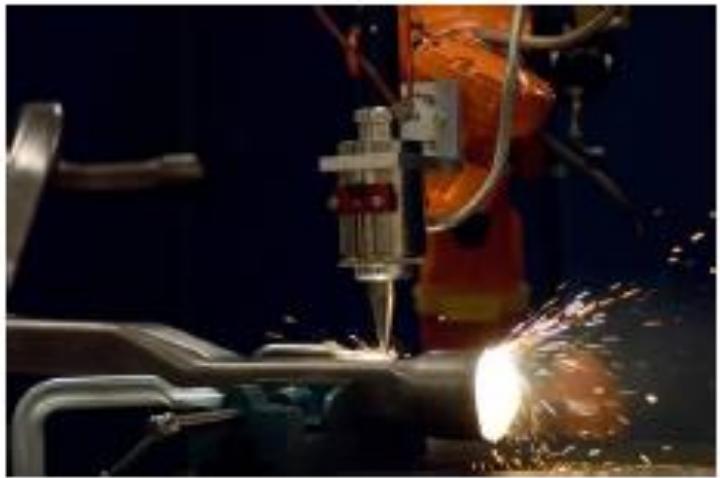
- 250, 400, 800, 1000+ W of laser power
- Wavelength of 1070nm (NIR)
- One 7 or 15 um fiber core
- 0.34-0.41mm*mrad beam divergence

T x H x D = 60 x 33 x 4.7 cm

Efficiency (DC) > 35%

Building blocks (modules) for HPFLs





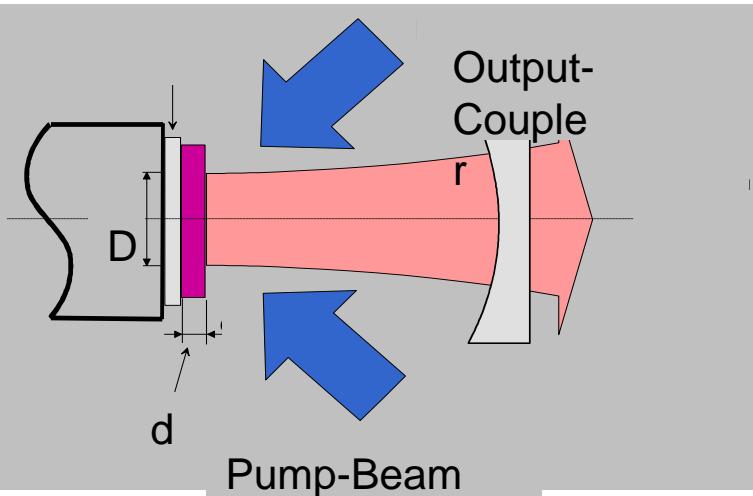
ALAV 2009



ALAV 2009

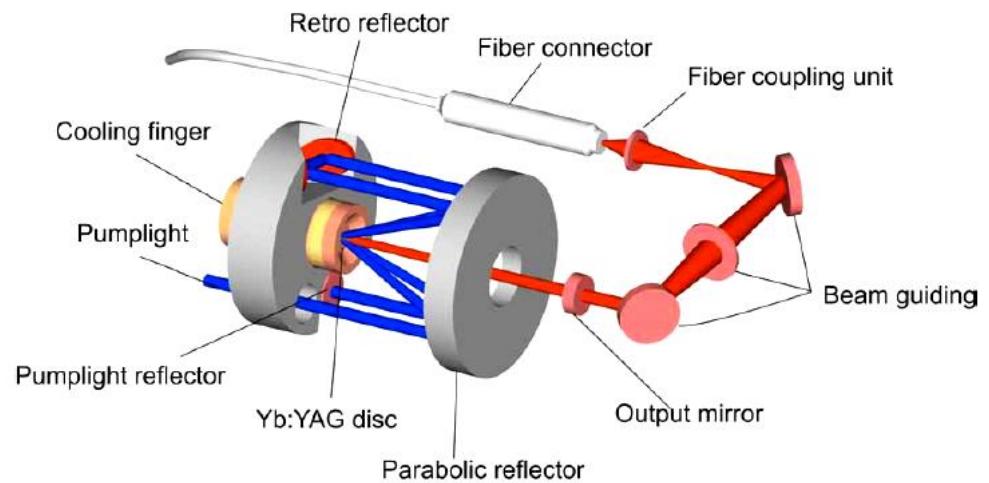
Thin Disk Lasers

Yb:YAG



>10 kW CW

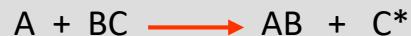
Requires multipass pumping



This principle does show 8 passages through the disc,
in actual fact more are performed.

Chemical Lasers

- population inversion is produced by a chemical reaction



- electrical power supply is not needed
- airborne lasers
- first chemical laser: 1964

chemical reaction:

- exothermic
- generation rate must be large enough to overcome spontaneous emission and collisional relaxation

Examples:

reaction	active medium	wavelength
$F + D_2 \rightarrow DF^* + D$	DF	3.5 - 4.1 μm
$Cl + HI \rightarrow HCl^* + I$	HCl	3.5 - 4.1 μm
$H + Br_2 \rightarrow HBr^* + Br$	HBr	4.0 - 4.7 μm
$F + H_2 \rightarrow HF^* + H$	HF	3.5 - 4.1 μm
$I + O_2^* \rightarrow I^* + O_2$	I	1.31 μm

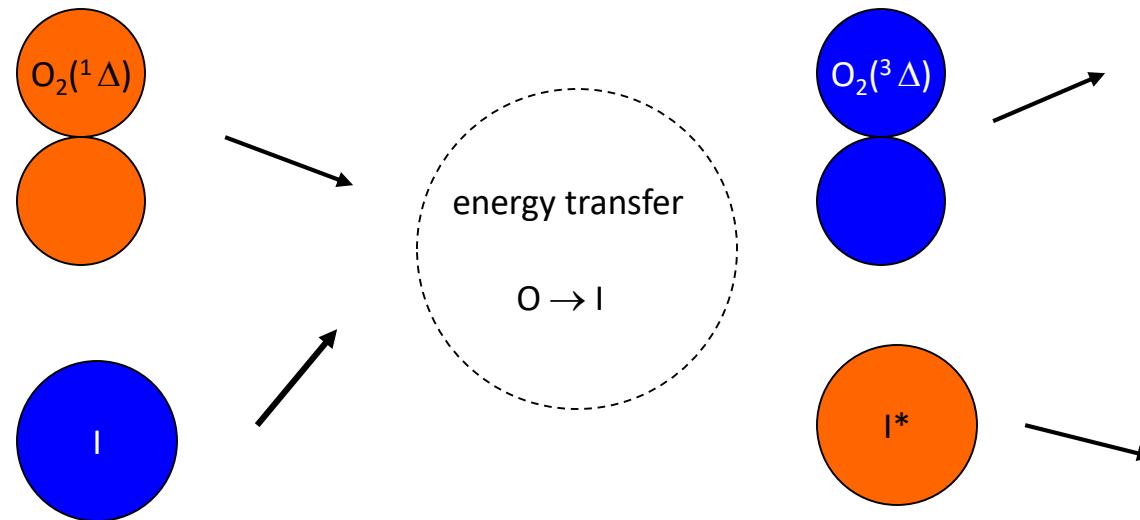
molecules in an excited vibrational state

atoms in an excited electronic state

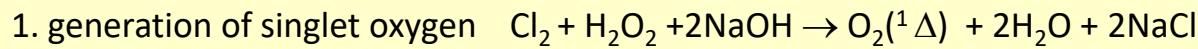
The chemical oxygen-iodine laser (COIL): MW CW Power !!

Singlet oxygen (dioxidene) has a >40 min lifetime.

chemical reaction:



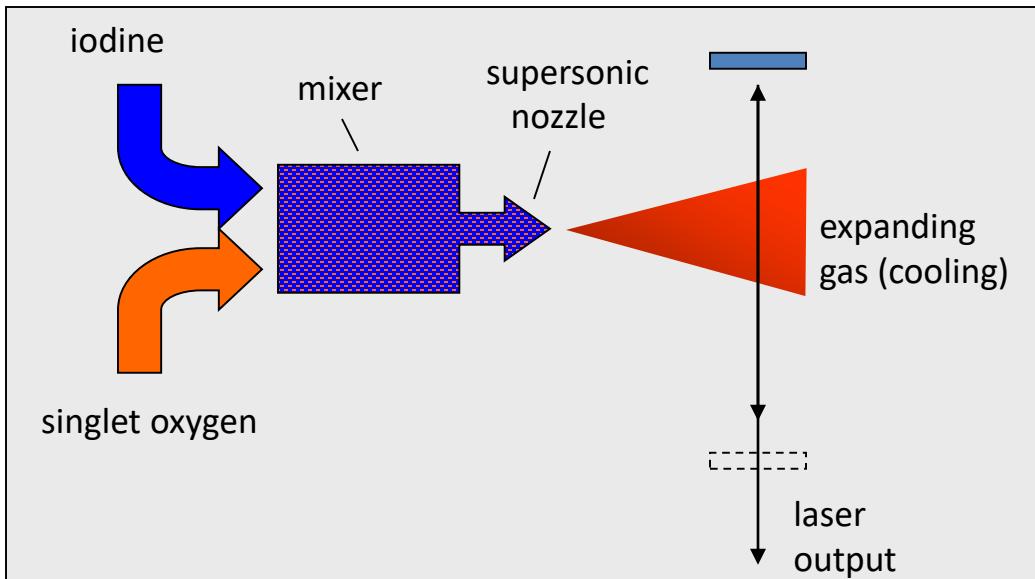
steps:



3. lasing of excited iodine

schematic diagram of a chemical iodine laser

parameters

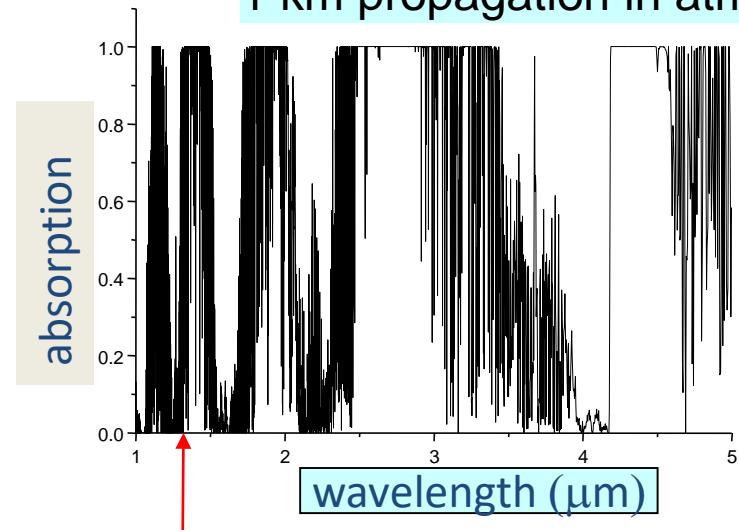


- MW ouput power
- wavelength **1.315** micron
- pulsed and cw

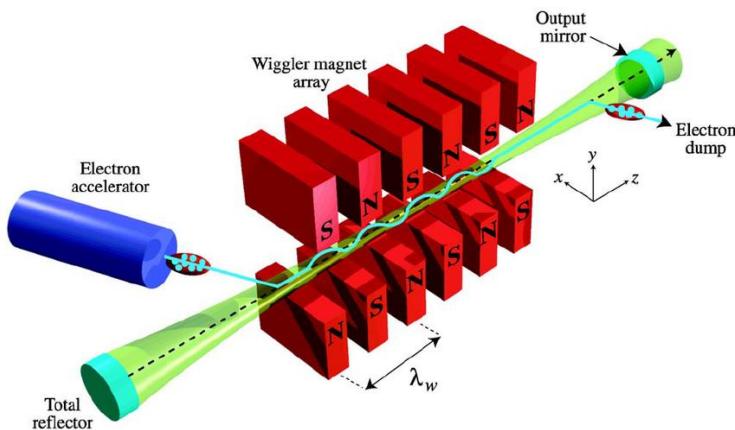


atmospheric absorption

1 km propagation in atmosphere



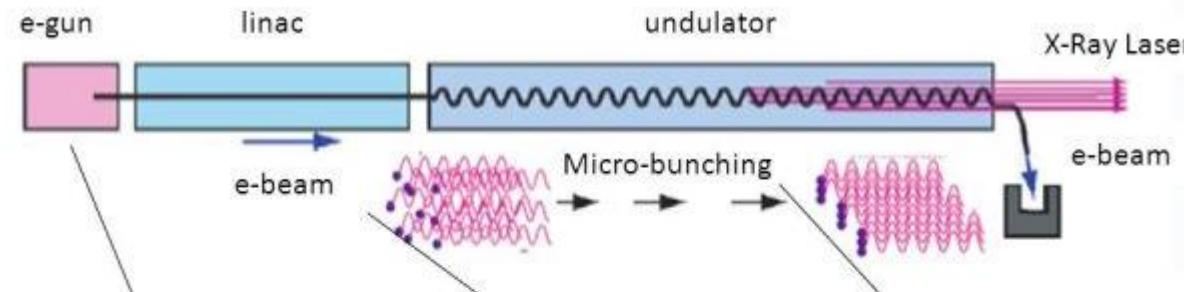
Free Electron Laser (FEL)



wiggler period

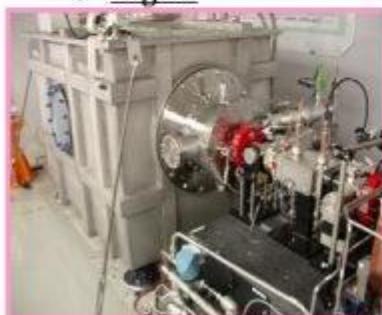
$$\lambda_r \approx \frac{\lambda_w}{2\gamma^2}$$

$$\gamma = \frac{1 + K^2/2}{\sqrt{1 - \beta^2}} > 10^4$$

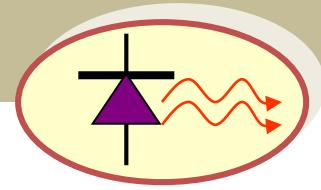


$$K \propto |B|$$

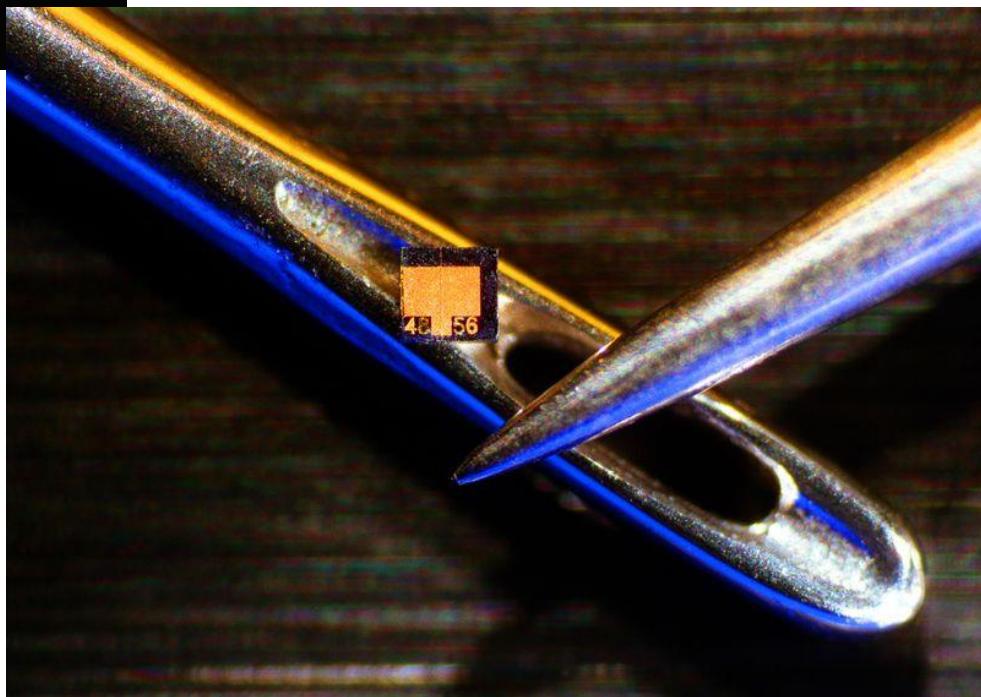
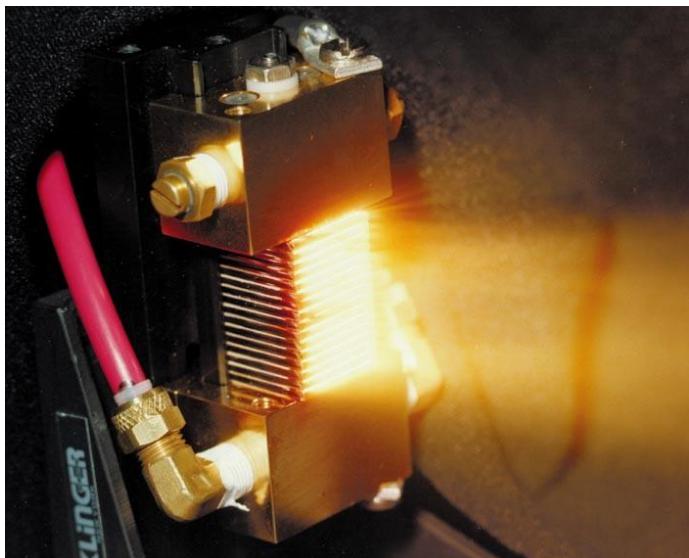
wiggler strength
(often < 1)



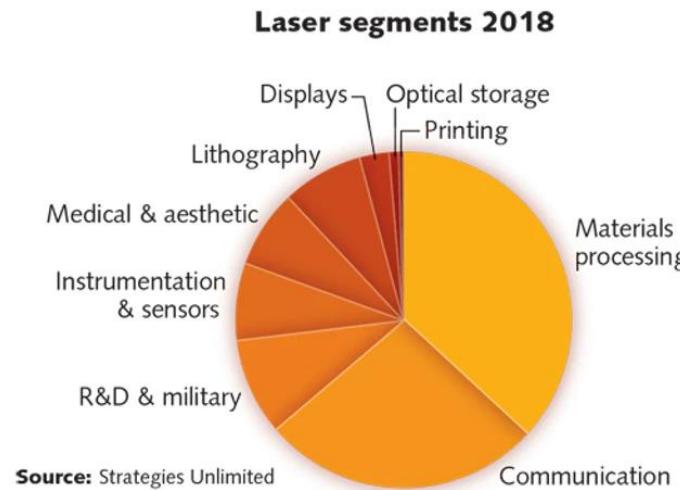
Semiconductor Lasers



A Variety of Small Laser Diodes

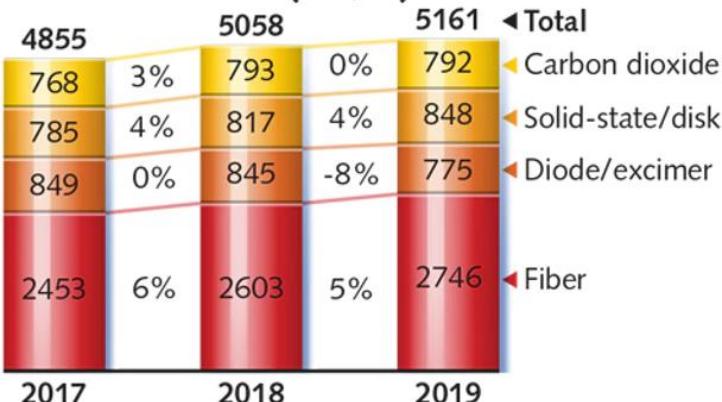


Laser Market and Applications



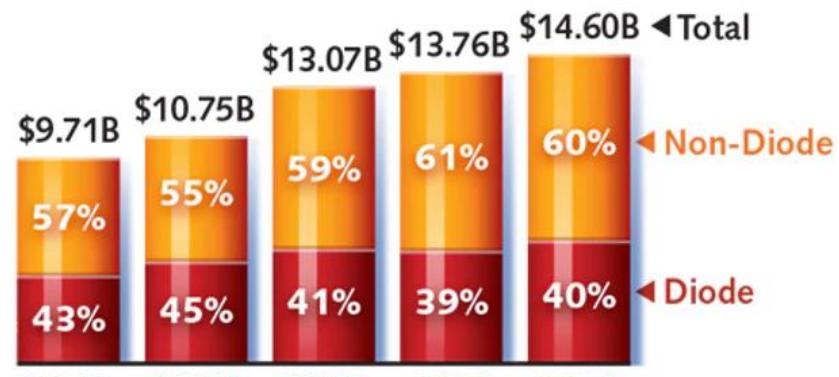
Industrial Laser Revenues by Laser Type

(US\$M)

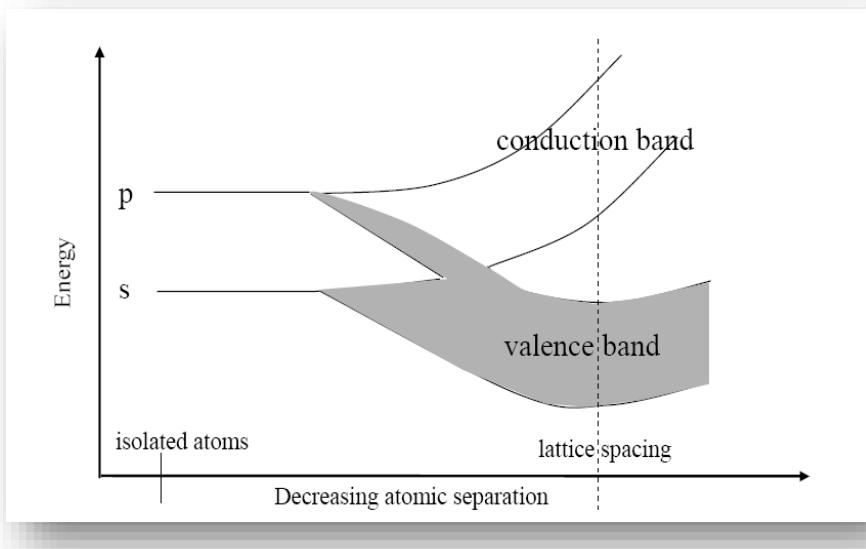


Source: Strategies Unlimited

Laser revenues and 2019 forecast

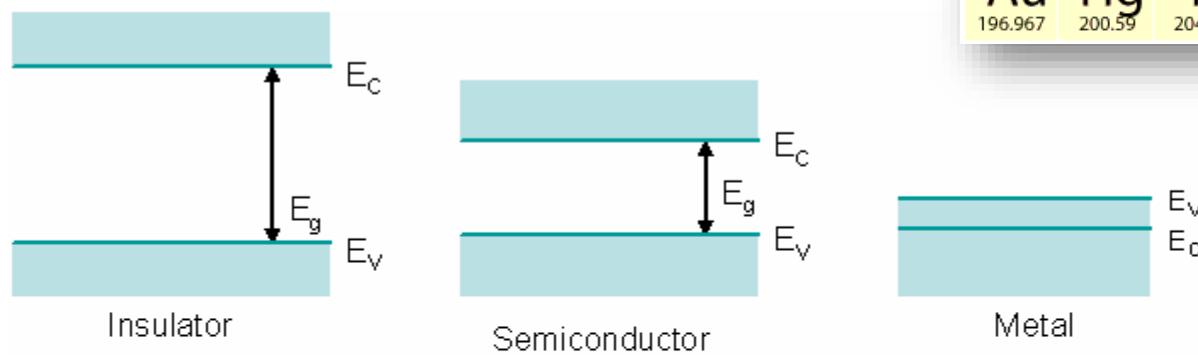


Source: Strategies Unlimited



What is a semiconductor?

		VIIIA						
		He 4.003						
		B 10.811	C 12.011	N 14.007	O 15.999	F 18.998	Ne 20.183	
IB	IIB	Al 26.982	Si 28.086	P 30.974	S 32.064	Cl 35.453	Ar 39.948	
29	30	Cu 63.54	Zn 65.37	Ga 69.72	Ge 72.59	As 74.922	Se 78.96	Br 83.80
47	48	Ag 107.870	Cd 112.40	In 114.82	Sn 118.69	Sb 121.75	Te 127.60	Xe 131.30
79	80	Au 196.967	Hg 200.59	Tl 204.37	Pb 207.19	Bi 208.980	Po (210)	At (210)
								Rn (222)



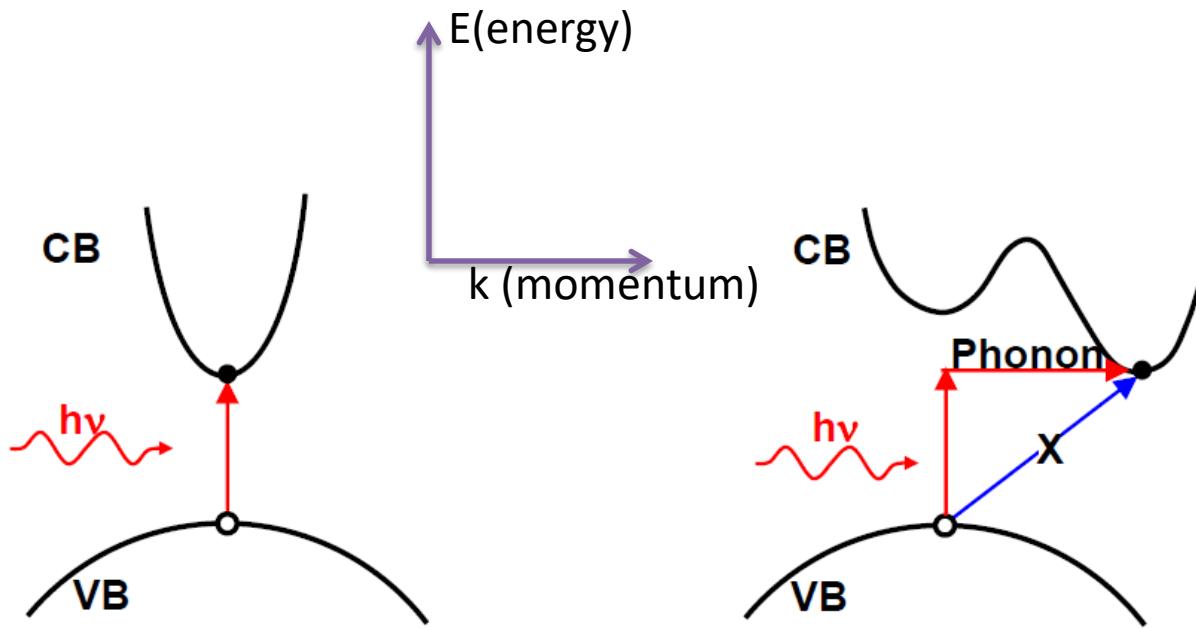
If $\uparrow T$

- $\uparrow R$ METAL
- $\downarrow R$ SEMICONDUCTOR

Band gap values for some semiconductors

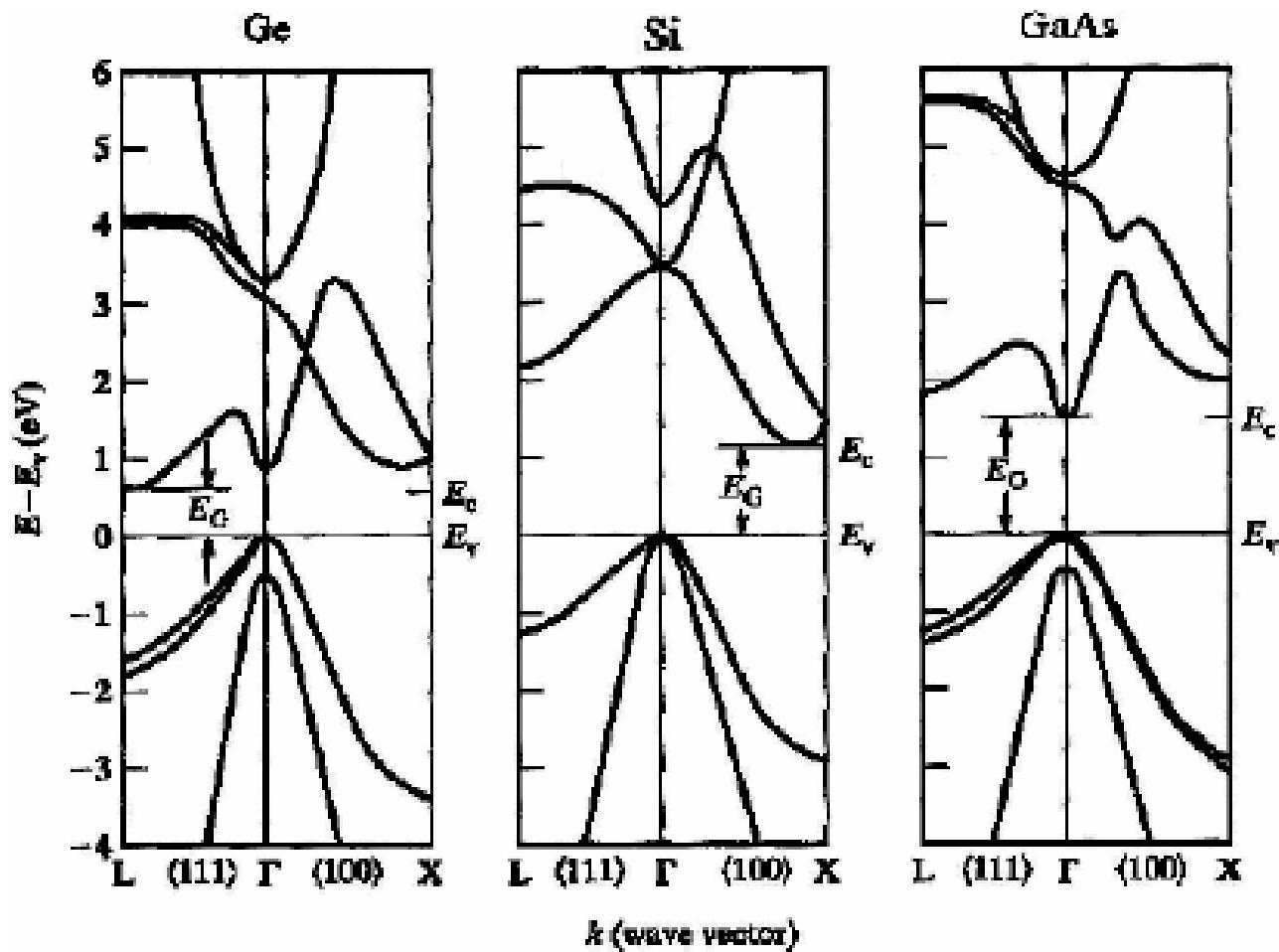
	Ge	Si	GaAs	GaN
E_g (eV)	0,66	1,12	1,42	3,44

Direct-Gap vs. Indirect-Gap

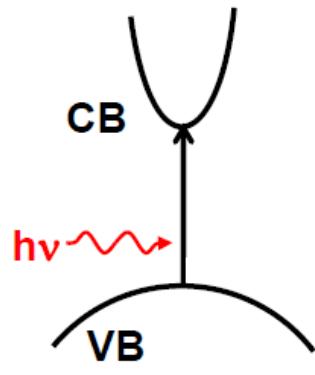


- Direct bandgap materials
 - CB minimum and VB maximum occur at the same k
 - Examples
 - GaAs, InP, InGaAsP
 - $(Al_xGa_{1-x})As$, $x < 0.45$
- Indirect bandgap materials
 - CB minimum and VB maximum occur at different k
 - Example
 - Si, Ge
 - $(Al_xGa_{1-x})As$, $x > 0.45$
 - Not “optically active”

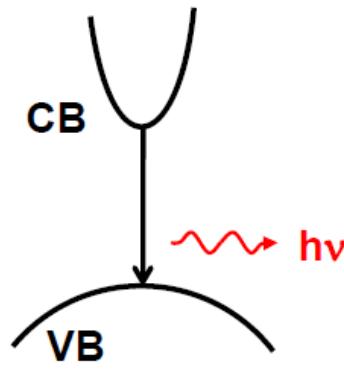
E-k diagrams



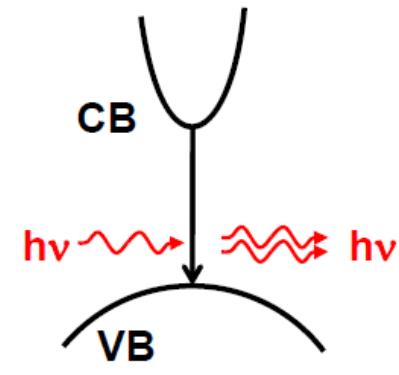
Optical Interactions in a Direct-Gap Semiconductor



Absorption



Spontaneous Emission



Stimulated Emission

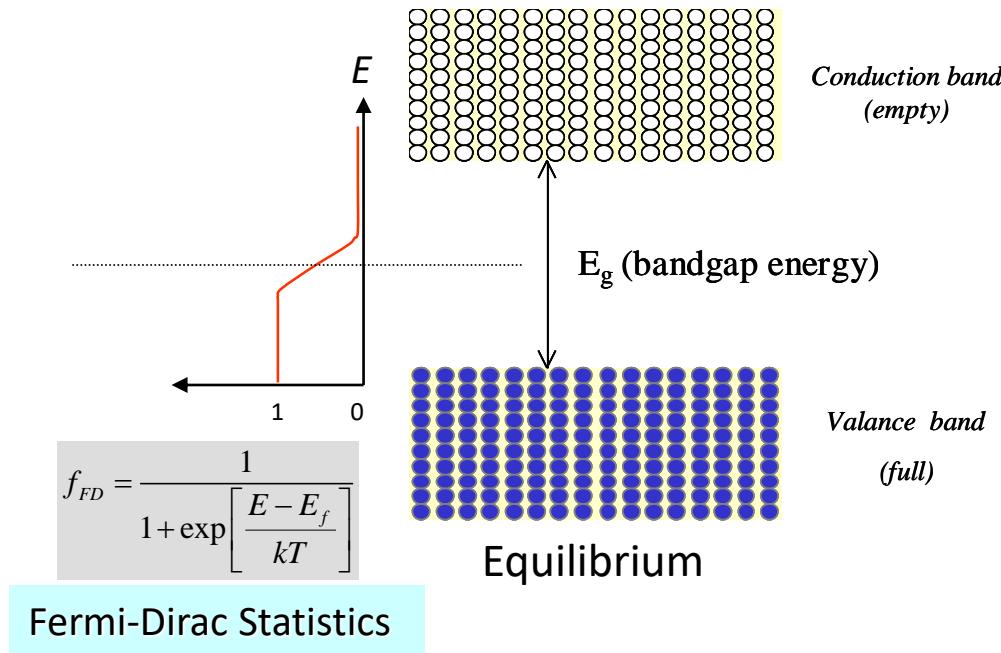
↓
**Photodetectors;
Solar Cells**

↓
LED

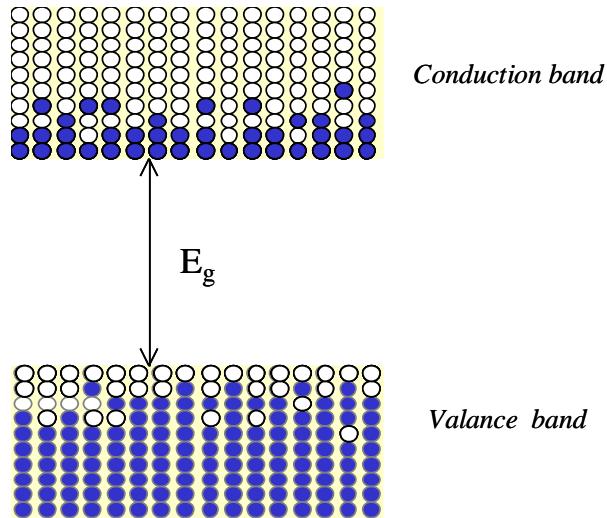
↓
**Optical Amplifiers;
Semiconductor Lasers**

A Brief Introduction to Semiconductors

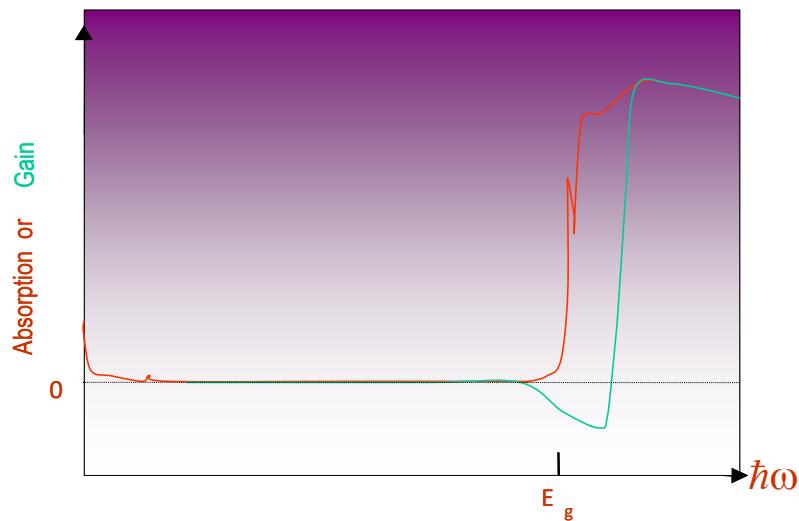
Energy Bands



<http://britneyspears.ac/lasers.htm> !!!???



Nonequilibrium Electron-Hole Injection



Example

GaAs

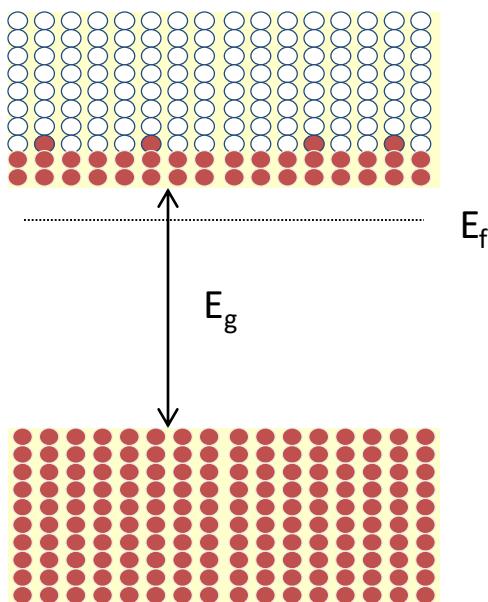
$E_g=1.4 \text{ eV}$

$(\lambda_g=850 \text{ nm})$

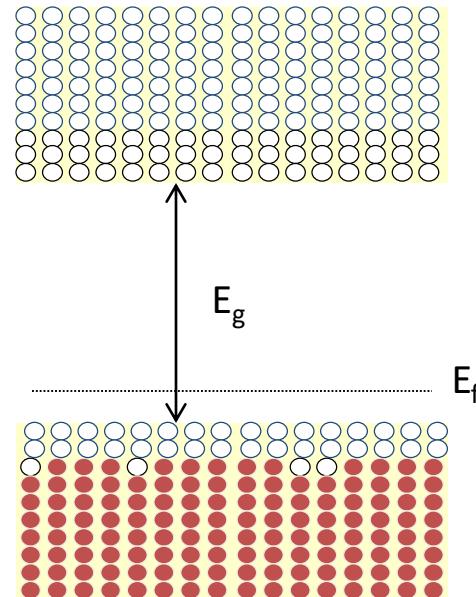
p-n junctions

Doping with Impurities

n-type



p-type



Examples: GaAs doped with Br

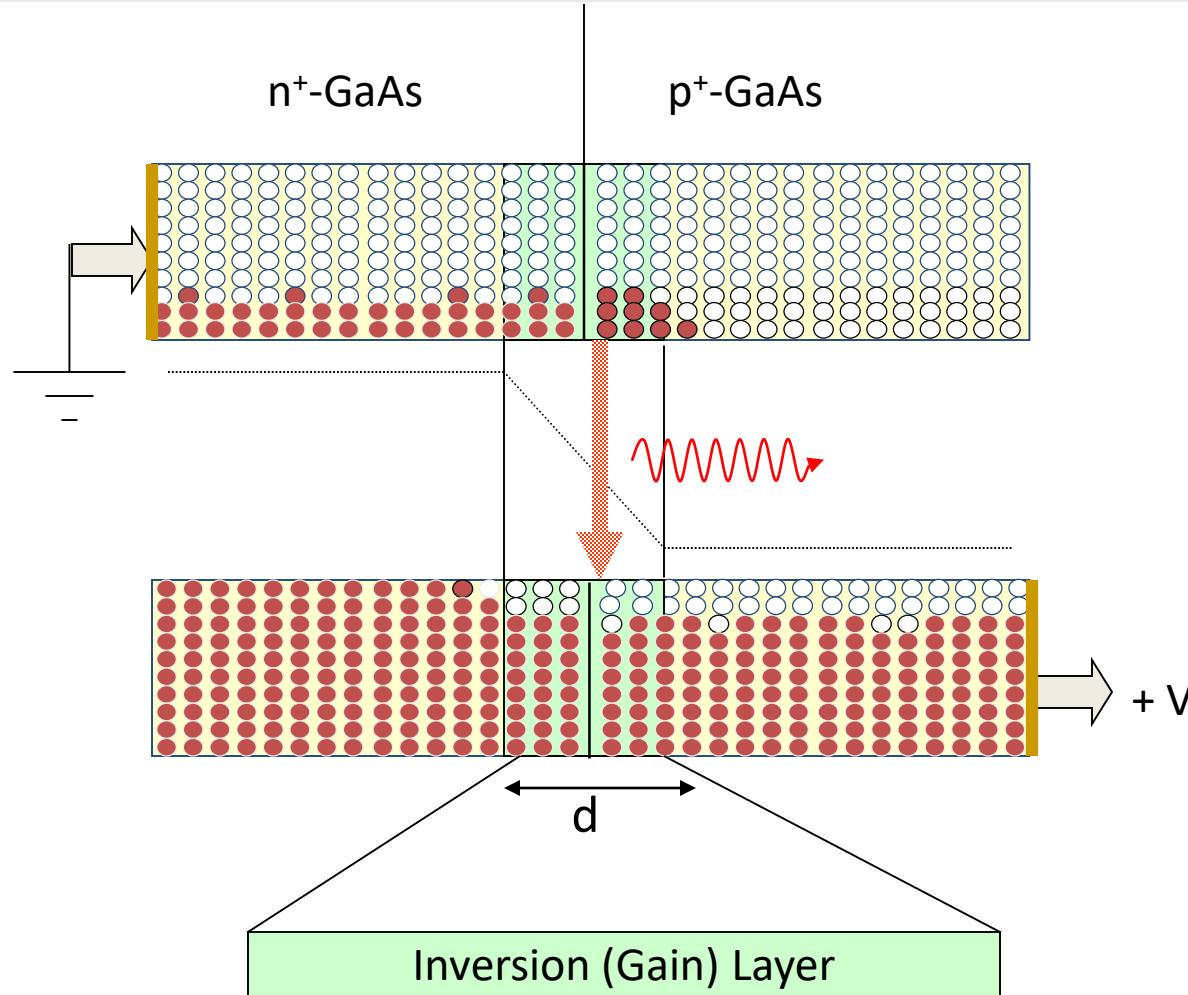
Si doped with P

Examples: GaAs doped with Zn

Si doped with Al

Semiconductor junction lasers

Forward-Biased p-n Junction (LED)

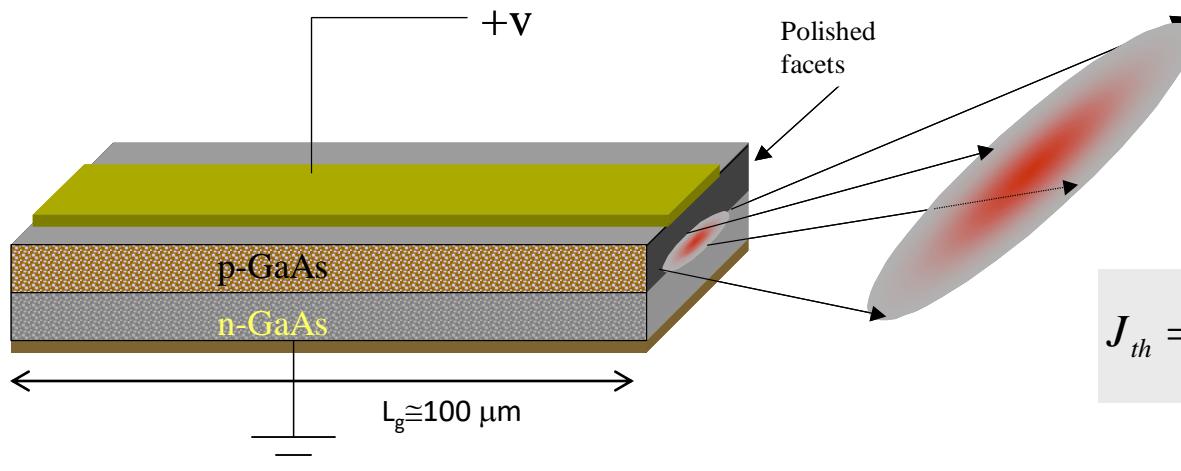


Current Density Threshold

$$J_{th} = \frac{N_{e,h}ed}{\tau_r}$$

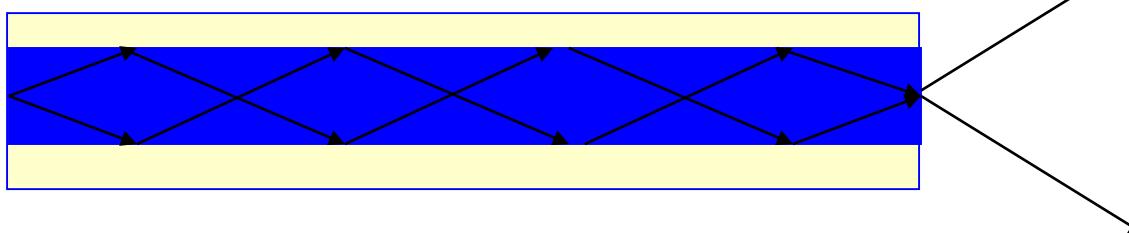
Recombination time

Edge-Emitting Homojunction Laser Diodes



$$J_{th} = \frac{N_{e,h}ed}{\tau_r}$$

- **Waveguide Modes**



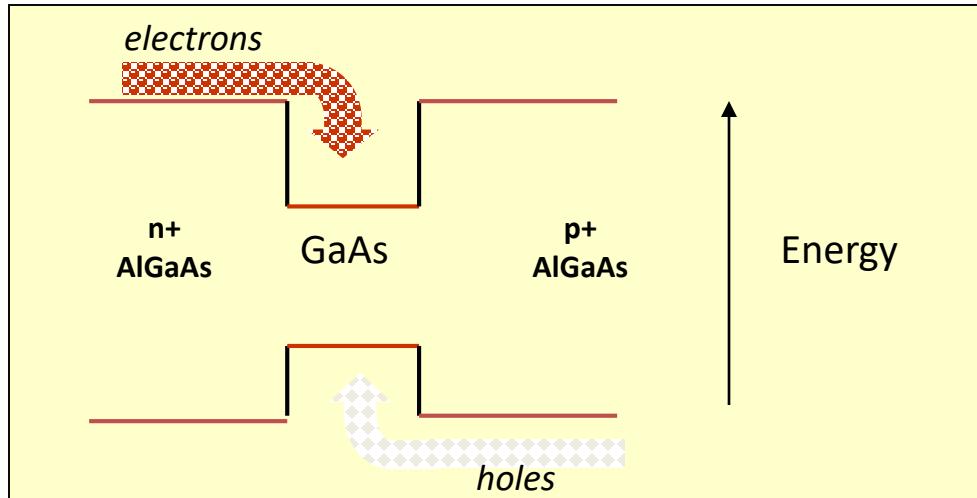
Homojunction Lasers have very high current threshold mainly because.

- *Electrons and holes are free to diffuse and therefore dilute the gain (no carrier confinement)*
- *Optical mode has poor overlap with gain (no optical confinement or guiding)*

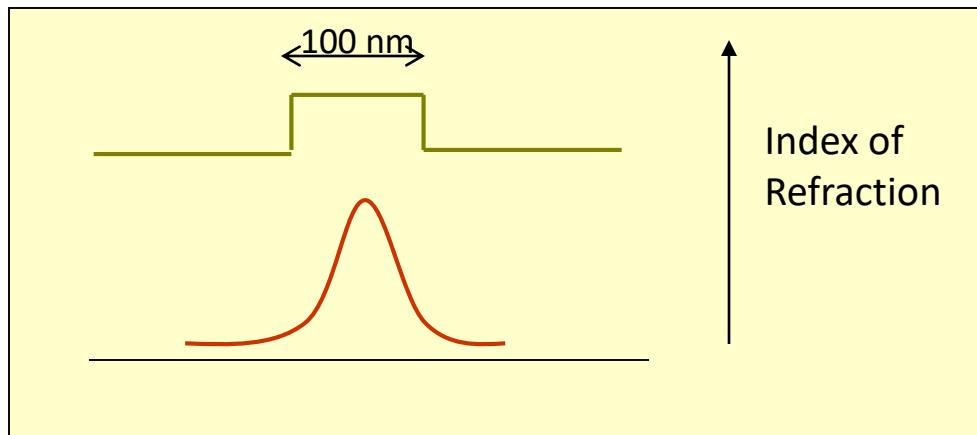
12.3 Heterojunction Lasers Diodes

A fortunate coincidence:

$n \uparrow$ when $E_g \downarrow$

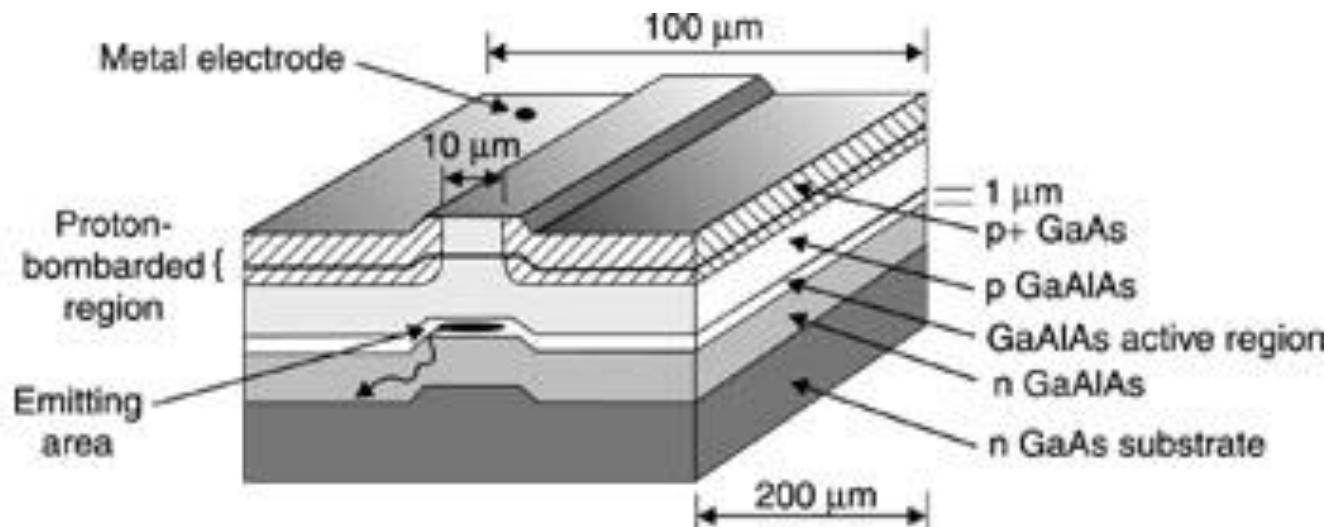


Carrier confinement

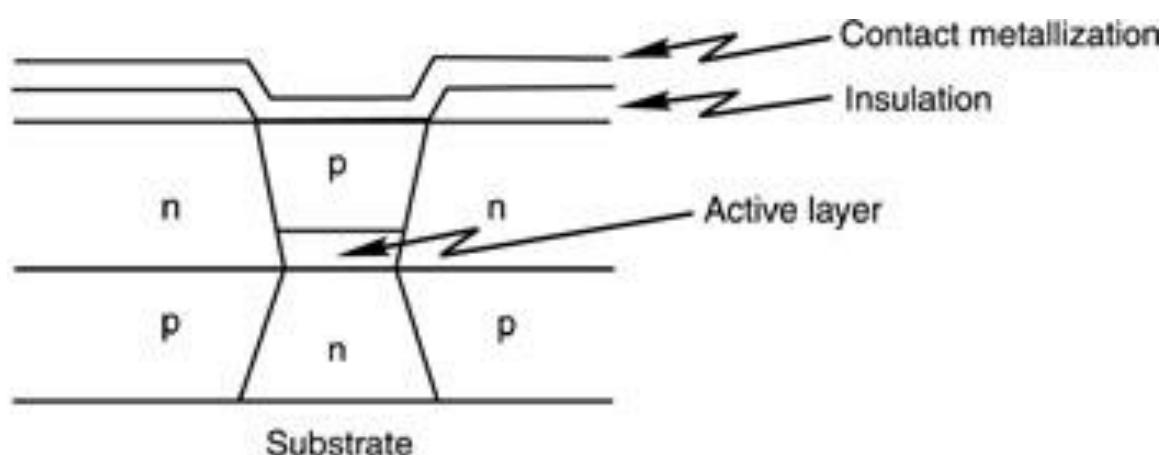


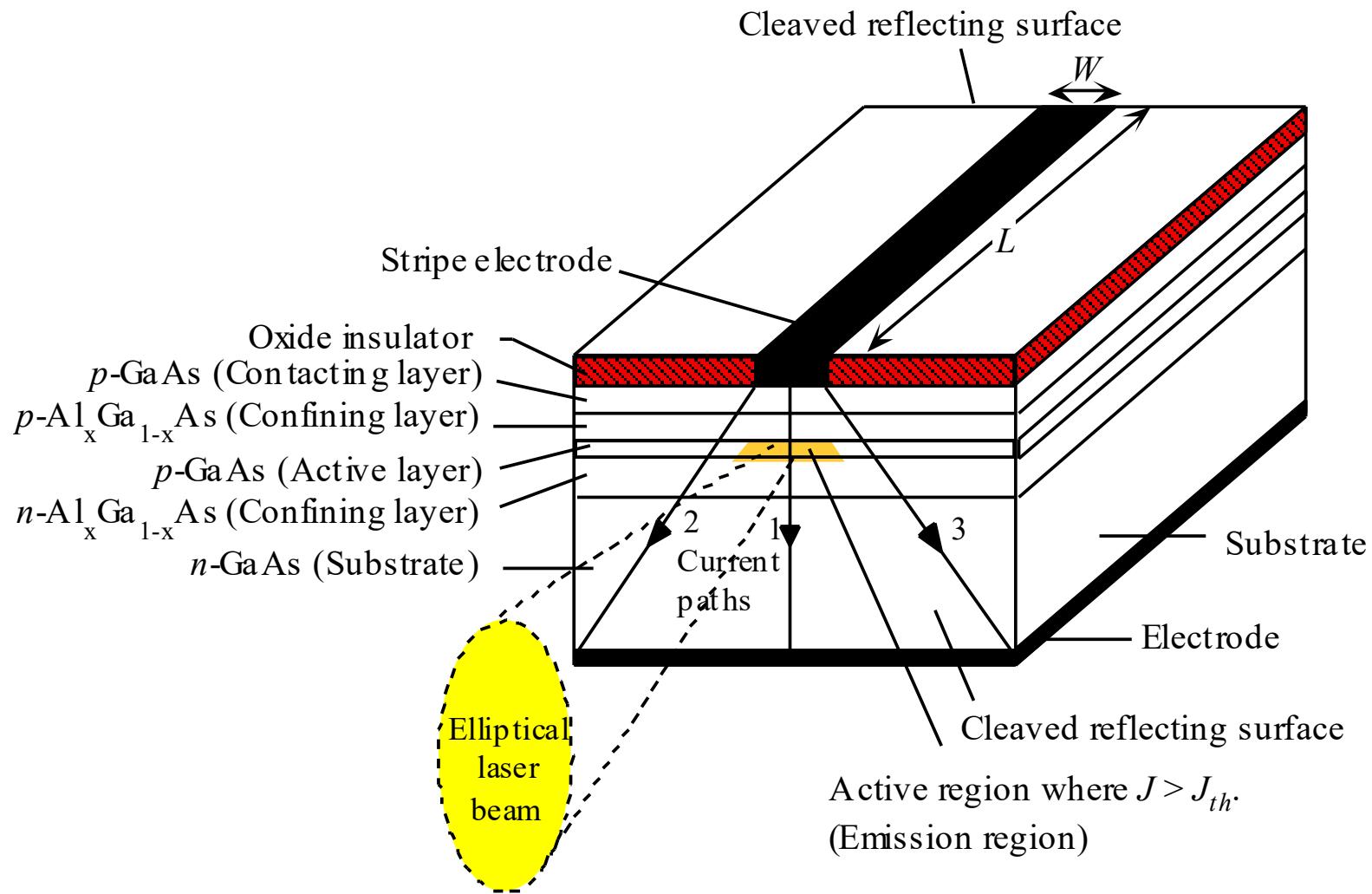
Mode confinement

Edge-Emitting Heterojunction Laser Diodes



Edge-Emitting Buried Heterojunction Laser Diodes

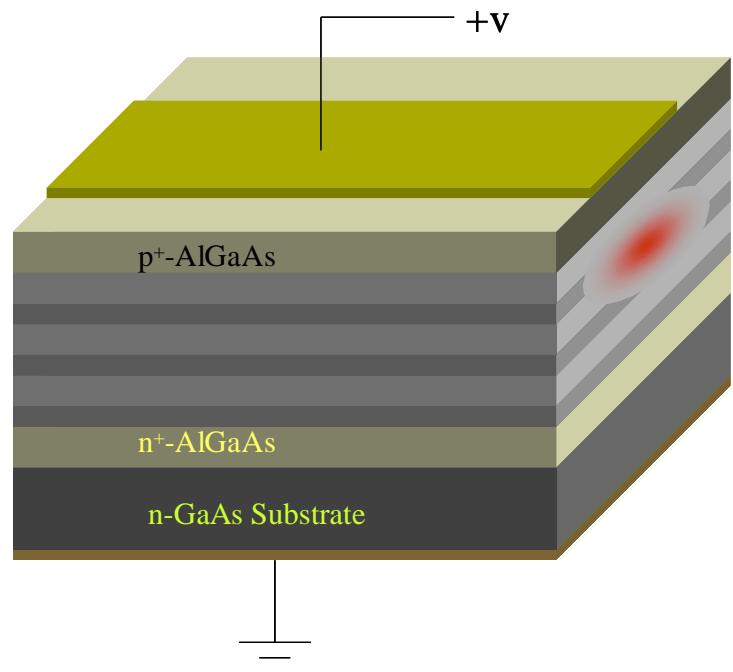
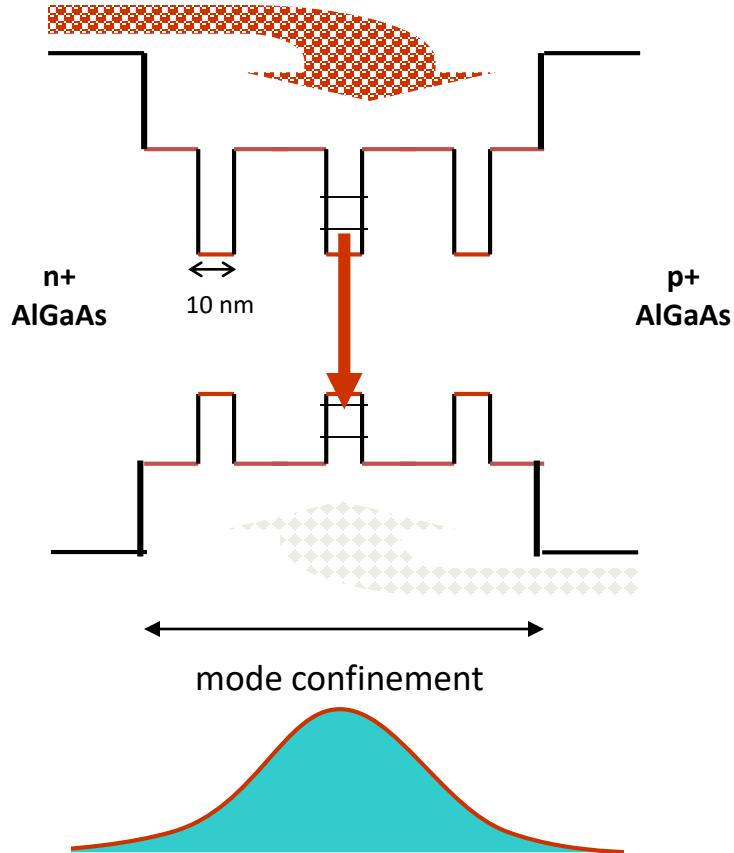




Schematic illustration of the the structure of a double heterojunction stripe contact laser diode

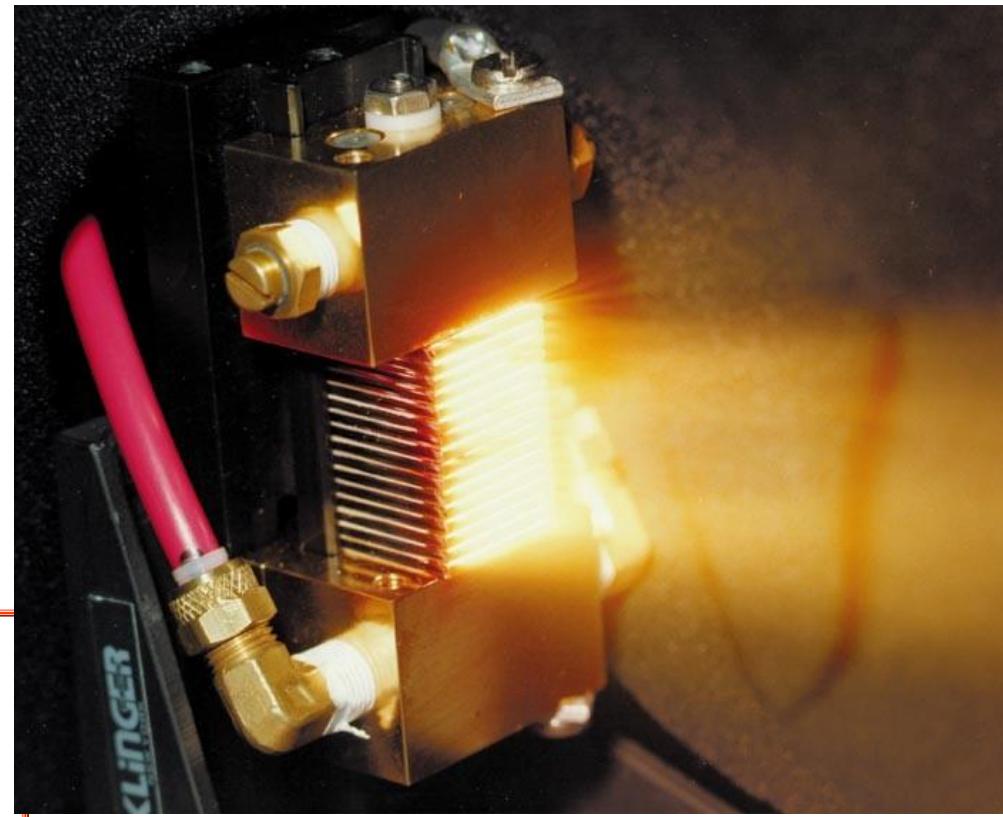
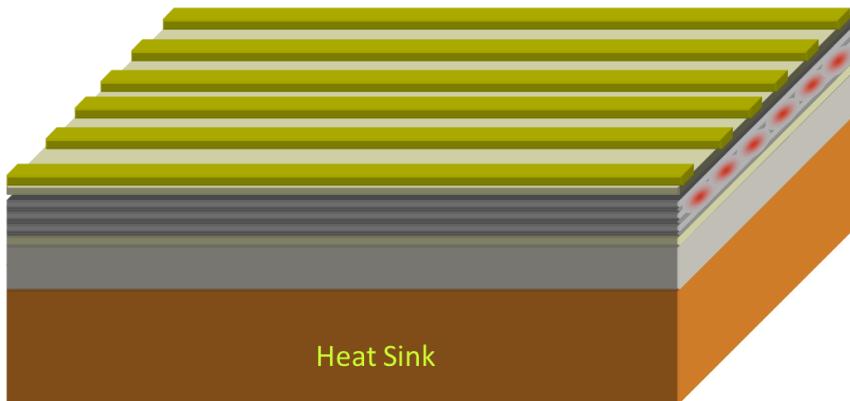
12.4 Quantum Well Lasers

Multiple Quantum Well (MQW) Lasers



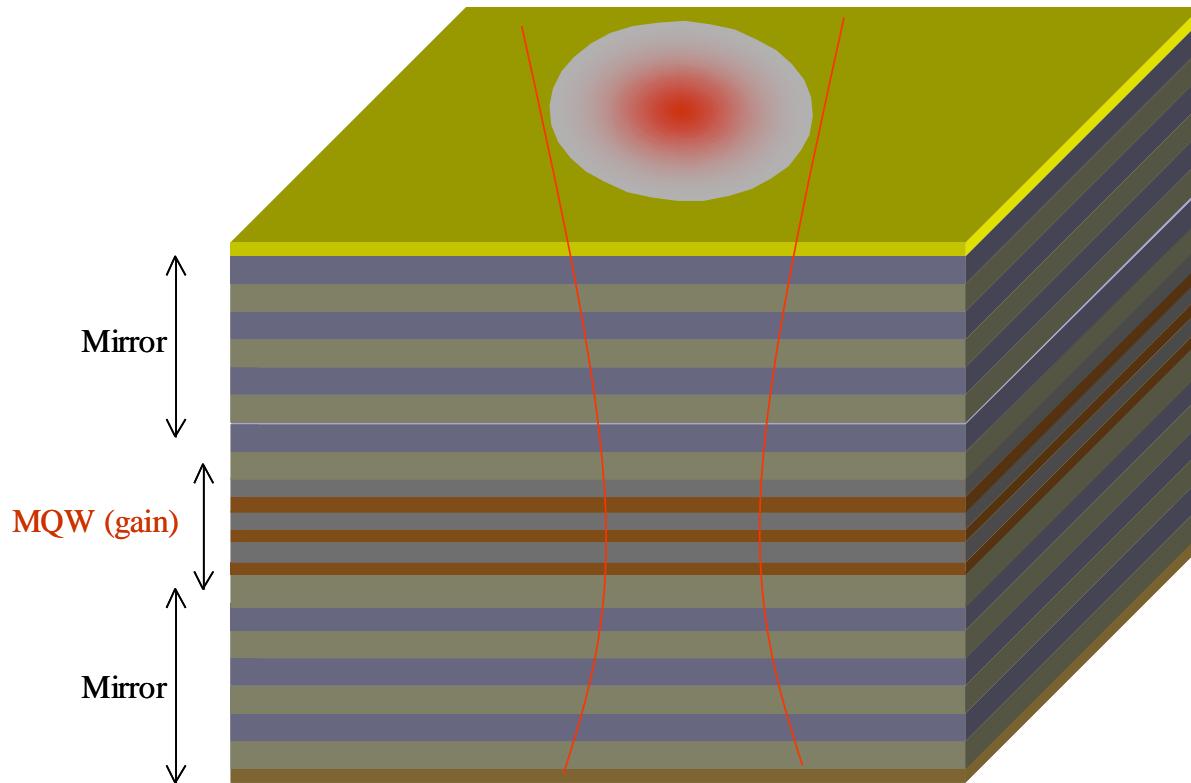
Epitaxial Growth

High Power Diode Bars



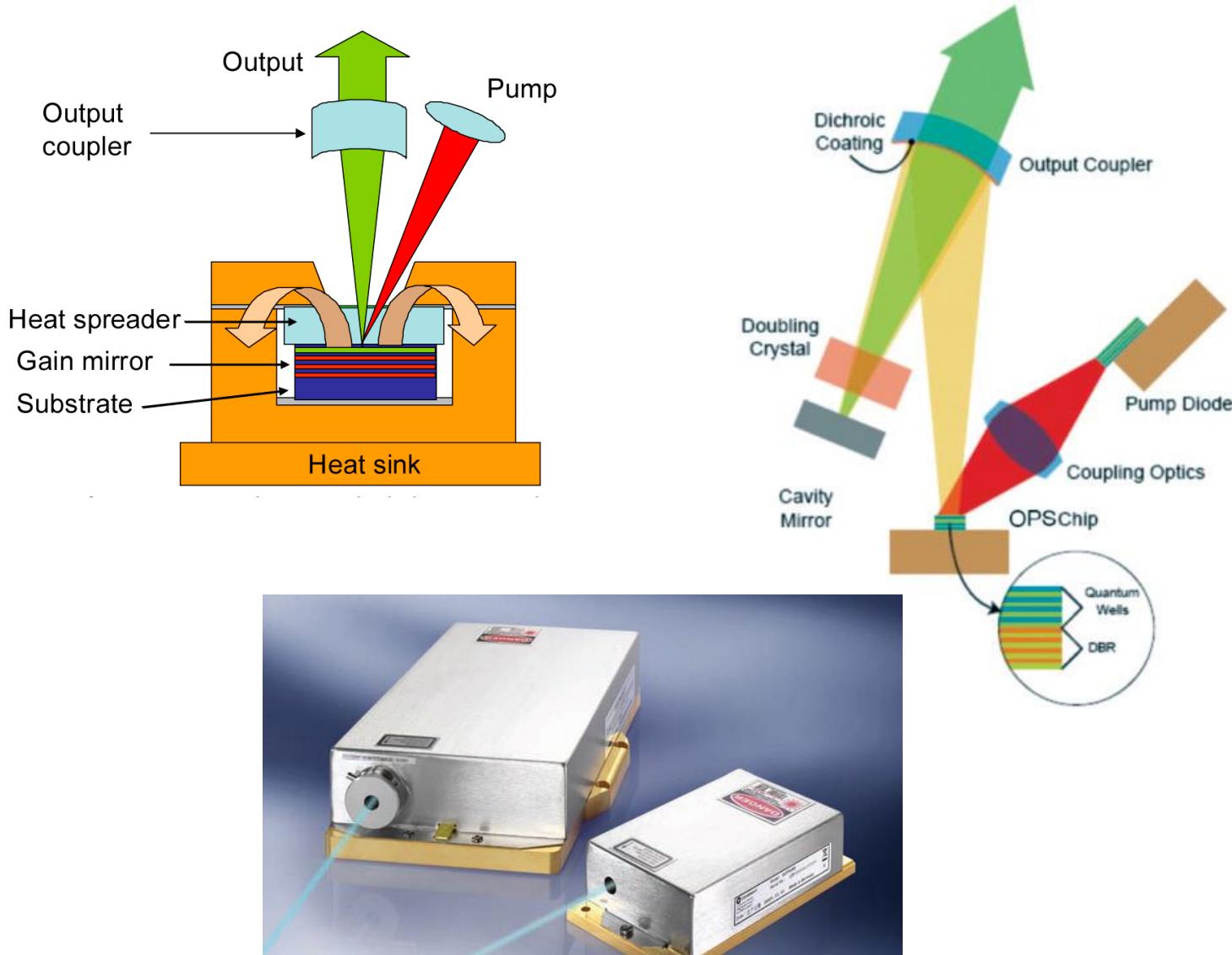
- $P > 100 \text{ W (cw)}$
- Diode-pumping solid-state lasers (DPSS)
- Material Processing
- ...

Vertical Cavity Surface Emitting Lasers (VCSEL)



- Good mode quality couples to fiber efficiently for telecom applications
- Single mode operation
- 2-D structures can be made
- Low power

Optically-Pumped Semiconductor Lasers (OPSL)



Laser Diodes Cover the Spectrum

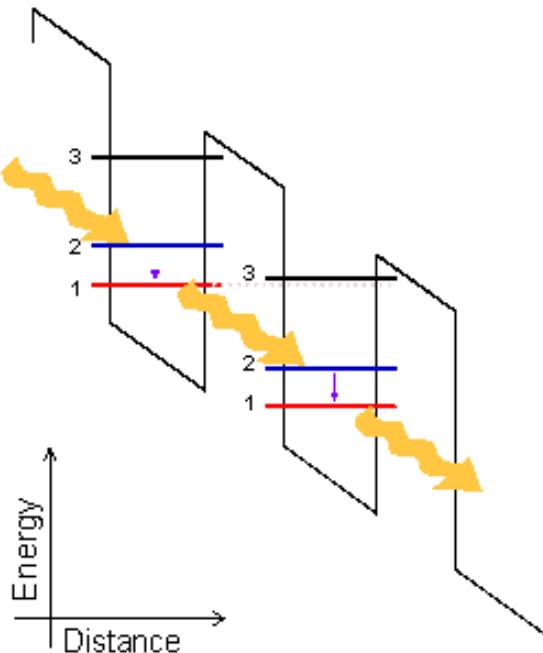
Compound	Spectral Region	Notes
$\text{Al}_x\text{Ga}_{1-x}\text{N}$ GaN $\text{In}_x\text{Ga}_{1-x}\text{N}$	<i>uv</i> <i>uv (350 nm)</i> <i>blue (480-400 nm)</i>	data storage, display
$\text{Ga}_x\text{I}_{1-x}\text{P}$ ($x=0.5$) $\text{Ga}_x\text{Al}_{1-x}\text{As}$ ($x=0-0.45$)	<i>670 nm</i> <i>620-895 nm</i>	display
GaAs $\text{In}_x\text{Ga}_{1-x}\text{As}$ ($x=0.2$)	<i>904 nm</i> <i>980 nm</i>	diode pumping solid-state and fiber lasers.
$\text{In}_x\text{Ga}_{1-x}\text{As}_y\text{P}_{1-y}$ ($x=0.73$, $y=0.58$) ($x=0.58$, $y=0.9$)	<i>1100-1650</i> <i>1310 nm</i> <i>1550 nm</i>	Telecom

PbSSe	<i>4200-8000 nm</i>	cryogenic
PbSnTe	<i>6300-29,000 nm</i>	cryogenic

12.5 Recent Advances: Quantum Cascade Lasers

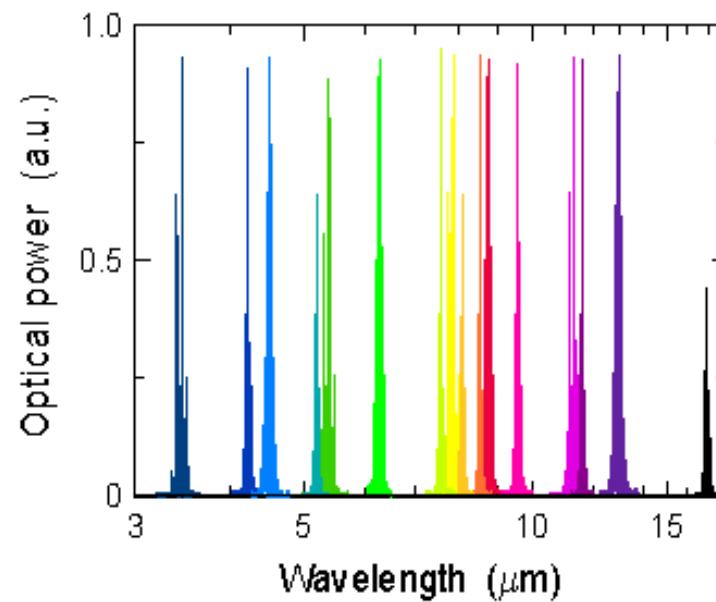
Original concept and theoretical prediction

R. F. Kazarinov and R. A. Suris, Fiz. Tekh. Poluprovodn., 5, pp. 797-800, (1971).



- Energy levels of electrons (3,2,1) in quantum wells strongly depend on layer thickness
- Laser photon created by an electron jumping between energy levels 1 and 2
→ therefore wavelength is determined by choice of layer thicknesses
- Many photons created by an electron cascading through many quantum wells

Wide wavelength-range of QC lasers



QC lasers cover entire mid-infrared wavelength range (3.4 - 17 μm) by tailoring layer thicknesses of the same material

THE END !



"Mr. Osborne, may I be excused? My brain is full."